

#### RC210xxB

VersaClock 7 Programmable Clock Generator Family

The RC210xxB devices are Renesas' seventhgeneration high-performance programmable clock generators for compute, data-communications, and industrial applications.

#### **Applications**

- High-performance computing
- Data center accelerators
- Enterprise storage
- Switches and routers
- Industrial

#### **Features**

- 169fs RMS phase jitter at 156.25MHz
- PCIe® Gen6 Common Clock (CC) 27fs RMS
- PCIe SRIS and SRNS support
- 1kHz to 200MHz LVCMOS outputs
- 1kHz to 650MHz LVDS/LP-HCSL outputs

- LP-HCSL integrates  $100\Omega$  or  $85\Omega$  terminations
- Simple AC-coupling to LVPECL and CML
- Programmable General Purpose Inputs (GPI × 4) and General Purpose Input/Outputs (GPIO × 5)
- 1MHz I<sup>2</sup>C, 400kHz SMBus or 20MHz SPI support
- Configuration via factory-programmed One-Time Programmable (OTP) memory, serial interface or external I2C EEPROM
- OTP holds up to four complete or 27 partial configurations
- 1.8V, 2.5V, 3.3V, -40° to +85°C operation
- RC21012B 12 output pairs
  - 6 × 6 mm 48-QFN, integrated crystal option
- RC21008B 8 output pairs
  - 5 × 5 mm 40-QFN, integrated crystal option
- RC21005B 5 output pairs
  - 4 x 4 mm 32-QFN with integrated crystal

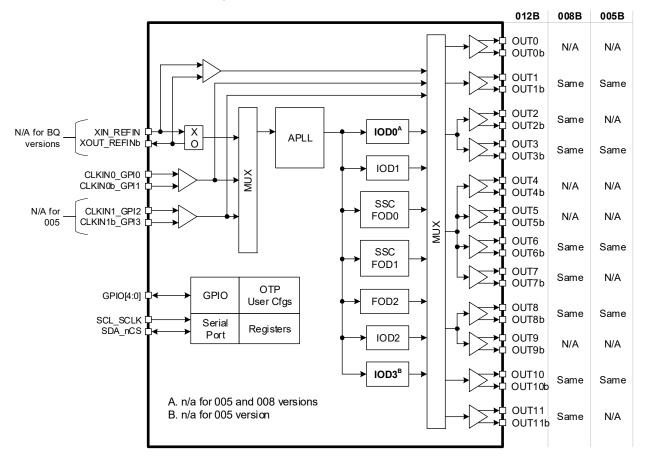


Figure 1. RC210xxB Block Diagram

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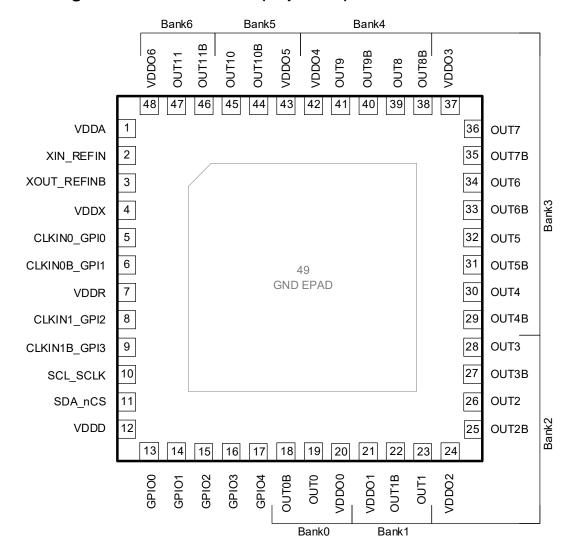


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#### 1. Pin Information

#### 1.1 Pin Assignments – RCxxx12B (Top View)



## 1.2 Pin Descriptions – RCxxx12B

Table 1. RCxxx12B Pin Descriptions

Number	Name	Туре	Description
1	VDDA	Power	Analog power supply. SeeTable 8 for supported voltages.
2	XIN_REFIN	I	Crystal Input or differential reference clock positive input / CMOS single-ended reference clock input.
3	XOUT_REFIND	I/O	Crystal Output or differential reference clock negative input.  This pin should be connected to a crystal. If an oscillator is connected to XIN_REFIN, then this pin must be left unconnected.
4	VDDX	Power	Crystal oscillator power supply. See Table 8 for supported voltages.
5	CLKIN0_GPI0	I	Differential clock positive input / CMOS single-ended reference clock input or general purpose input pin GPI0.
6	CLKIN0b_GPI1	I	Differential clock negative input / CMOS single-ended reference clock input or general purpose input pin GPI1.

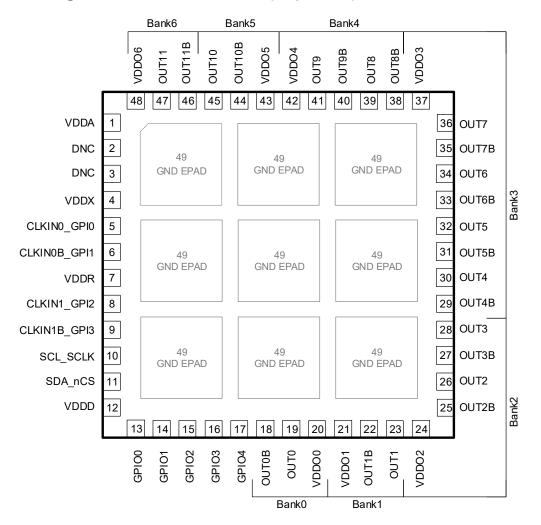
Table 1. RCxxx12B Pin Descriptions (Cont.)

9 CLKIN1_GPI2 I purpose input pin GPI2.  9 CLKIN1b_GPI3 I Differential clock negative input / CMOS single-ended reference clock input or genera purpose input pin GPI3.  10 SCL_SCLK I SPI Mode: Serial Clock This pin is 3.3V tolerant.	Number	Name	Туре	Description
9 CLKINT_GPI2 I purpose input pin GPI2. 9 CLKINTb_GPI3 I Differential clock negative input / CMOS single-ended reference clock input or genera purpose input pin GPI3. 10 SCL_SCLK I SPI Mode: SPC interface bi-directional clock. SPI Mode: Serial Clock This pin is 3.3V tolerant. 11 SDA_nCS I IZC Mode: PC interface bi-directional data in open-drain mode. SPI Mode: Chip Select (active low) This pin is 3.3V tolerant. 11 SDA_nCS I IZC Mode: PC interface bi-directional data in open-drain mode. SPI Mode: Chip Select (active low) This pin is 3.3V tolerant. 12 VDDD Power Digital core and GPIO power supply. See Table 8 for supported voltages. When programming the OTP, this supply must be 2.5V or 3.3V. 13 GPIO0 I/O General purpose input/output. 14 GPIO1 I/O General purpose input/output. 15 GPIO2 I/O General purpose input/output. 3-level logic input during power-up and CMOS level logic after unless set to 3-level. 16 GPIO3 I/O General purpose input/output. 17 GPIO4 I/O General purpose input/output. 18 nOUT0b O Output Clock 0 negative. 19 OUT0 O Output Clock 0 negative. 20 VDDO0 Power Power supply for output bank 0 and IOD 0. See Table 8 for supported voltages. 21 VDDO1 Power Power supply for output bank 0 and IOD 1. See Table 8 for supported voltages. 22 OUT1b O Output Clock 1 negative. 23 OUT1 O Output Clock 1 negative. 24 VDDO2 Power Power supply for output bank 1 and IOD 1. See Table 8 for supported voltages. 25 OUT2b O Output Clock 1 positive. 26 OUT2b O Output Clock 2 negative. 27 OUT3b O Output Clock 2 negative. 28 OUT3 O Output Clock 3 negative. 30 OUT4 O Output Clock 3 positive. 31 OUT5b O Output Clock 4 negative. 32 OUT1b O Output Clock 4 positive. 33 OUT6 O Output Clock 5 positive. 34 OUT6 O Output Clock 6 positive. 35 OUT7b O Output Clock 6 positive. 36 OUT7b O Output Clock 6 positive. 37 OUT7b O Output Clock 6 positive.	7	VDDR	Power	CLKIN (receiver) power supply. See Table 8 for supported voltages.
SCL_SCLK  I Durpose input pin GPI3.  IZC Mode: PC interface bi-directional clock.  SPI Mode: Serial Clock This pin is 3.3V tolerant.  IZC Mode: PC interface bi-directional clock.  SPI Mode: Serial Clock This pin is 3.3V tolerant.  IZC Mode: PC interface bi-directional data in open-drain mode. SPI Mode: Chip Select (active low) This pin is 3.3V tolerant.  IZC Mode: PC interface bi-directional data in open-drain mode. SPI Mode: Chip Select (active low) This pin is 3.3V tolerant.  IZC Mode: PC interface bi-directional data in open-drain mode. SPI Mode: Chip Select (active low) This pin is 3.3V tolerant.  IZC Mode: PC interface bi-directional data in open-drain mode. SPI Mode: Chip Select (active low) This pin is 3.3V tolerant.  IZC Mode: PC interface bi-directional data in open-drain mode. SPI Mode: Chip Select (active low) This pin is 3.3V tolerant.  IZC Mode: PC interface bi-directional data in open-drain mode. SPI Mode: Chip Select (active low) This pin is 3.3V tolerant.  IZC Mode: PC interface bi-directional data in open-drain mode. SPI Mode: Chip Select (active low) This pin is 3.3V tolerant.  IZC Mode: PC interface bi-directional data in open-drain mode. SPI Mode: Chip Select (active low) This pin is 3.3V tolerant.  IZC Mode: PC interface bi-directional data in open-drain mode. SPI Mode: Chip Select (active low) This pin is 3.3V tolerant.  IZC Mode: PC interface bi-directional data in open-drain mode. SPI Mode: Chip Select (active low) This pin is 3.3V tolerant.  IZC Mode: PC interface bi-directional data in open-drain mode. SPI Mode: Chip Select (active low) This pin is 3.3V tolerant.  IZC Mode: PC interface bi-directional data in open-drain mode. SPI Mode: Chip Select (active low) This pin is 3.3V tolerant.  IZC Mode: PC interface bi-directional data in open-drain mode. SPI Mode: Chip Select (active low) IXI General purpose input/output.  IXI GPIO1  IXI GENERAL Mode: PC interface bi-directional data in open-drain mode. SPI Mode: Chip Select (active low) IXI General purpose input/output.  IXI GPIO1  IXI GPI	8	CLKIN1_GPI2	I	Differential clock positive input / CMOS single-ended reference clock input or general purpose input pin GPI2.
10 SCL_SCLK 1 SPI Mode: Serial Clock This pin is 3.3V tolerant. 11 SDA_nCS 1 IZC Mode: IPC interface bi-directional data in open-drain mode. SPI Mode: Chip Select (active low) This pin is 3.3V tolerant. 12 VDDD 10 Power 11 Power 12 Digital core and GPIO power supply. See Table 8 for supported voltages. When programming the OTP, this supply must be 2.5V or 3.3V. 13 GPIO0 I/O General purpose input/output. 3-level logic input during power-up and CMOS level logic after unless set to 3-level. 14 GPIO1 I/O General purpose input/output. 3-level logic input during power-up and CMOS level logic after unless set to 3-level. 15 GPIO2 I/O General purpose input/output. 3-level logic input during power-up and CMOS level logic after unless set to 3-level. 16 GPIO3 I/O General purpose input/output. 17 GPIO4 I/O General purpose input/output. 18 nOUT0b O Output Clock 0 negative. 19 OUT0 O Output Clock 0 negative. 20 VDDO0 Power Power supply for output bank 0 and IOD 0. See Table 8 for supported voltages. 21 VDDO1 Power Power supply for output bank 1 and IOD 1. See Table 8 for supported voltages. 22 OUT1b O Output Clock 1 negative. 23 OUT1 O Output Clock 1 positive. 24 VDDO2 Power Power supply for output bank 2 and FOD 0. See Table 8 for supported voltages. 25 OUT2b O Output Clock 1 positive. 26 OUT2 O Output Clock 2 positive. 27 OUT3b O Output Clock 2 positive. 28 OUT3 O Output Clock 3 negative. 39 OUT4 O Output Clock 4 negative. 30 OUT4 O Output Clock 4 negative. 31 OUT5 O Output Clock 5 positive. 32 OUT5 O Output Clock 6 negative. 33 OUT6b O Output Clock 6 negative. 34 OUT6 O Output Clock 7 negative. 35 OUT7b O Output Clock 6 negative.	9	CLKIN1b_GPI3	I	Differential clock negative input / CMOS single-ended reference clock input or general purpose input pin GPI3.
11 SDA_nCS I (active low) This pin is 3.3V tolerant.  12 VDDD Power Digital core and GPIO power supply. See Table 8 for supported voltages. When programming the OTP, this supply must be 2.5V or 3.3V.  13 GPIO0 I/O General purpose input/output. 3-level logic input during power-up and CMOS level logic after unless set to 3-level.  14 GPIO1 I/O General purpose input/output. 3-level logic input during power-up and CMOS level logic after unless set to 3-level.  15 GPIO2 I/O General purpose input/output. 3-level logic input during power-up and CMOS level logic after unless set to 3-level.  16 GPIO3 I/O General purpose input/output. 3-level logic input during power-up and CMOS level logic after unless set to 3-level.  17 GPIO4 I/O General purpose input/output.  18 nOUT0b O Output Clock 0 negative.  19 OUT0 O Output Clock 0 positive.  20 VDDO0 Power Power supply for output bank 0 and IOD 0. See Table 8 for supported voltages.  21 VDDO1 Power Power supply for output bank 1 and IOD 1. See Table 8 for supported voltages.  22 OUT1b O Output Clock 1 negative.  23 OUT1 O Output Clock 1 positive.  24 VDDO2 Power Power supply for output bank 2 and FOD 0. See Table 8 for supported voltages.  25 OUT2b O Output Clock 2 negative.  26 OUT2b O Output Clock 3 negative.  27 OUT3b O Output Clock 3 negative.  28 OUT3 O Output Clock 3 positive.  29 OUT4b O Output Clock 3 positive.  29 OUT4b O Output Clock 3 positive.  30 OUT4 O Output Clock 3 negative.  31 OUT5b O Output Clock 5 negative.  32 OUT5b O Output Clock 5 negative.  33 OUT6b O Output Clock 6 positive.  34 OUT6 O Output Clock 6 positive.  35 OUT7b O Output Clock 6 positive.	10	SCL_SCLK	I	SPI Mode: Serial Clock
Programming the OTP, this supply must be 2.5V or 3.3V.  GPIO0 I/O General purpose input/output. 3-level logic input during power-up and CMOS level logic after unless set to 3-level.  I/O General purpose input/output. 3-level logic input during power-up and CMOS level logic after unless set to 3-level.  GPIO2 I/O General purpose input/output. 3-level logic input during power-up and CMOS level logic after unless set to 3-level.  GPIO3 I/O General purpose input/output. 3-level logic input during power-up and CMOS level logic after unless set to 3-level.  GPIO3 I/O General purpose input/output.  GPIO4 I/O General purpose input/output.  GPIO5 I/O General purpose input/output.  O Output Clock 0 negative.  O Output Clock 0 positive.  O VDDO0 Power Power supply for output bank 0 and IOD 0. See Table 8 for supported voltages.  VDDO1 Power Power supply for output bank 1 and IOD 1. See Table 8 for supported voltages.  OUT1b O Output Clock 1 negative.  OUTput Clock 1 positive.  OUTput Clock 1 positive.  OUTput Clock 2 positive.  OUT2b O Output Clock 2 positive.  OUT3b O Output Clock 2 positive.  OUT3b O Output Clock 3 negative.  OUT9b O Output Clock 4 negative.  OUT9b O Output Clock 4 negative.  OUT9b O Output Clock 4 positive.  OUT9b O Output Clock 5 positive.  OUT9b O Output Clock 6 negative.  OUT9b O Output Clock 6 positive.  OUT9b O Output Clock 6 positive.	11	SDA_nCS	I	
13 GPIOU I/O 3-level logic input during power-up and CMOS level logic after unless set to 3-level.  14 GPIO1 I/O General purpose input/output. 3-level logic input during power-up and CMOS level logic after unless set to 3-level.  15 GPIO2 I/O General purpose input/output. 3-level logic input during power-up and CMOS level logic after unless set to 3-level.  16 GPIO3 I/O General purpose input/output.  17 GPIO4 I/O General purpose input/output.  18 nOUT0b O Output Clock 0 negative.  19 OUT0 O Output Clock 0 positive.  20 VDDO0 Power Power supply for output bank 0 and IOD 0. See Table 8 for supported voltages.  21 VDDO1 Power Power supply for output bank 1 and IOD 1. See Table 8 for supported voltages.  22 OUT1b O Output Clock 1 negative.  23 OUT1 O Output Clock 1 positive.  24 VDDO2 Power Power supply for output bank 2 and FOD 0. See Table 8 for supported voltages.  25 OUT2b O Output Clock 2 negative.  26 OUT2 O Output Clock 2 negative.  27 OUT3b O Output Clock 2 positive.  28 OUT3 O Output Clock 3 negative.  29 OUT4b O Output Clock 4 negative.  30 OUT4 O Output Clock 4 positive.  31 OUT5b O Output Clock 4 positive.  32 OUT5 O Output Clock 5 segative.  33 OUT6b O Output Clock 5 positive.  34 OUT6 O Output Clock 6 negative.  35 OUT7b O Output Clock 6 positive.	12	VDDD	Power	
3-level logic input during power-up and CMOS level logic after unless set to 3-level.    15   GPIO2	13	GPIO0	I/O	
15 GPIO2 I/O 3-level logic input during power-up and CMOS level logic after unless set to 3-level.  16 GPIO3 I/O General purpose input/output.  17 GPIO4 I/O General purpose input/output.  18 nOUT0b O Output Clock 0 negative.  19 OUT0 O Output Clock 0 negative.  20 VDD00 Power Power supply for output bank 0 and IOD 0. See Table 8 for supported voltages.  21 VDD01 Power Power supply for output bank 1 and IOD 1. See Table 8 for supported voltages.  22 OUT1b O Output Clock 1 negative.  23 OUT1 O Output Clock 1 positive.  24 VDD02 Power Power supply for output bank 2 and FOD 0. See Table 8 for supported voltages.  25 OUT2b O Output Clock 2 negative.  26 OUT2 O Output Clock 2 negative.  27 OUT3b O Output Clock 2 positive.  28 OUT3 O Output Clock 3 negative.  29 OUT4b O Output Clock 3 positive.  29 OUT4b O Output Clock 4 negative.  30 OUT4 O Output Clock 4 negative.  31 OUT5b O Output Clock 4 positive.  32 OUT5 O Output Clock 5 negative.  33 OUT6b O Output Clock 6 negative.  34 OUT6 O Output Clock 6 negative.  35 OUT7b O Output Clock 6 positive.	14	GPIO1	I/O	
17 GPIO4 I/O General purpose input/output.  18 nOUT0b O Output Clock 0 negative.  19 OUT0 O Output Clock 0 positive.  20 VDD00 Power Power supply for output bank 0 and IOD 0. See Table 8 for supported voltages.  21 VDD01 Power Power supply for output bank 1 and IOD 1. See Table 8 for supported voltages.  22 OUT1b O Output Clock 1 negative.  23 OUT1 O Output Clock 1 positive.  24 VDD02 Power Power supply for output bank 2 and FOD 0. See Table 8 for supported voltages.  25 OUT2b O Output Clock 2 negative.  26 OUT2 O Output Clock 2 negative.  27 OUT3b O Output Clock 3 negative.  28 OUT3 O Output Clock 3 negative.  29 OUT4b O Output Clock 3 positive.  29 OUT4b O Output Clock 4 negative.  30 OUT4 O Output Clock 4 positive.  31 OUT5b O Output Clock 5 positive.  32 OUT5 O Output Clock 5 positive.  33 OUT6b O Output Clock 6 negative.  34 OUT6 O Output Clock 6 positive.  35 OUT7b O Output Clock 6 positive.	15	GPIO2	I/O	
18 nOUT0b O Output Clock 0 negative.  19 OUT0 O Output Clock 0 positive.  20 VDDO0 Power Power supply for output bank 0 and IOD 0. See Table 8 for supported voltages.  21 VDDO1 Power Power supply for output bank 1 and IOD 1. See Table 8 for supported voltages.  22 OUT1b O Output Clock 1 negative.  23 OUT1 O Output Clock 1 positive.  24 VDDO2 Power Power supply for output bank 2 and FOD 0. See Table 8 for supported voltages.  25 OUT2b O Output Clock 2 negative.  26 OUT2 O Output Clock 2 positive.  27 OUT3b O Output Clock 3 negative.  28 OUT3 O Output Clock 3 negative.  29 OUT4b O Output Clock 4 negative.  30 OUT4 O Output Clock 4 positive.  31 OUT5b O Output Clock 5 positive.  32 OUT5 O Output Clock 5 positive.  33 OUT6b O Output Clock 5 positive.  34 OUT6 O Output Clock 6 negative.  35 OUT7b O Output Clock 6 positive.	16	GPIO3	I/O	General purpose input/output.
19 OUTO O Output Clock 0 positive. 20 VDDO0 Power Power supply for output bank 0 and IOD 0. See Table 8 for supported voltages. 21 VDDO1 Power Power supply for output bank 1 and IOD 1. See Table 8 for supported voltages. 22 OUT1b O Output Clock 1 negative. 23 OUT1 O Output Clock 1 positive. 24 VDDO2 Power Power supply for output bank 2 and FOD 0. See Table 8 for supported voltages. 25 OUT2b O Output Clock 2 negative. 26 OUT2 O Output Clock 2 positive. 27 OUT3b O Output Clock 3 negative. 28 OUT3 O Output Clock 3 positive. 29 OUT4b O Output Clock 4 negative. 30 OUT4 O Output Clock 4 positive. 31 OUT5b O Output Clock 5 positive. 32 OUT5 O Output Clock 5 positive. 33 OUT6b O Output Clock 6 negative. 34 OUT6 O Output Clock 6 positive. 35 OUT7b O Output Clock 6 positive.	17	GPIO4	I/O	General purpose input/output.
20 VDDO0 Power Power supply for output bank 0 and IOD 0. See Table 8 for supported voltages. 21 VDDO1 Power Power supply for output bank 1 and IOD 1. See Table 8 for supported voltages. 22 OUT1b O Output Clock 1 negative. 23 OUT1 O Output Clock 1 positive. 24 VDDO2 Power Power supply for output bank 2 and FOD 0. See Table 8 for supported voltages. 25 OUT2b O Output Clock 2 negative. 26 OUT2 O Output Clock 2 positive. 27 OUT3b O Output Clock 3 negative. 28 OUT3 O Output Clock 3 negative. 29 OUT4b O Output Clock 4 negative. 30 OUT4 O Output Clock 4 positive. 31 OUT5b O Output Clock 4 positive. 32 OUT5 O Output Clock 5 negative. 33 OUT6b O Output Clock 6 negative. 34 OUT6 O Output Clock 6 positive. 35 OUT7b O Output Clock 6 positive.	18	nOUT0b	0	Output Clock 0 negative.
21 VDDO1 Power Power supply for output bank 1 and IOD 1. See Table 8 for supported voltages.  22 OUT1b O Output Clock 1 negative.  23 OUT1 O Output Clock 1 positive.  24 VDDO2 Power Power supply for output bank 2 and FOD 0. See Table 8 for supported voltages.  25 OUT2b O Output Clock 2 negative.  26 OUT2 O Output Clock 2 positive.  27 OUT3b O Output Clock 3 negative.  28 OUT3 O Output Clock 3 positive.  29 OUT4b O Output Clock 4 negative.  30 OUT4 O Output Clock 4 positive.  31 OUT5b O Output Clock 5 negative.  32 OUT5 O Output Clock 5 positive.  33 OUT6b O Output Clock 6 negative.  34 OUT6 O Output Clock 6 positive.  35 OUT7b O Output Clock 6 positive.	19	OUT0	0	Output Clock 0 positive.
22 OUT1b O Output Clock 1 negative. 23 OUT1 O Output Clock 1 positive. 24 VDDO2 Power Power supply for output bank 2 and FOD 0. See Table 8 for supported voltages. 25 OUT2b O Output Clock 2 negative. 26 OUT2 O Output Clock 2 positive. 27 OUT3b O Output Clock 3 negative. 28 OUT3 O Output Clock 3 positive. 29 OUT4b O Output Clock 4 negative. 30 OUT4 O Output Clock 4 positive. 31 OUT5b O Output Clock 5 negative. 32 OUT5 O Output Clock 5 negative. 33 OUT6b O Output Clock 6 negative. 34 OUT6 O Output Clock 6 positive. 35 OUT7b O Output Clock 6 positive.	20	VDD00	Power	Power supply for output bank 0 and IOD 0. See Table 8 for supported voltages.
OUT1 O Output Clock 1 positive.  Power Supply for output bank 2 and FOD 0. See Table 8 for supported voltages.  OUT2b O Output Clock 2 negative.  OUT3b O Output Clock 2 positive.  OUT3b O Output Clock 3 negative.  OUT3b O Output Clock 3 positive.  OUT4b O Output Clock 4 positive.  OUT4b O Output Clock 4 negative.  OUT4b O Output Clock 4 positive.  OUT4b O Output Clock 5 negative.  OUT5b O Output Clock 5 negative.  OUT5b O Output Clock 5 negative.  OUT5b O Output Clock 6 negative.  OUT6b O Output Clock 6 negative.  OUT6b O Output Clock 6 negative.  OUT6b O Output Clock 6 positive.  OUT6b O Output Clock 6 negative.	21	VDDO1	Power	Power supply for output bank 1 and IOD 1. See Table 8 for supported voltages.
24     VDDO2     Power     Power supply for output bank 2 and FOD 0. See Table 8 for supported voltages.       25     OUT2b     O Output Clock 2 negative.       26     OUT2     O Output Clock 2 positive.       27     OUT3b     O Output Clock 3 negative.       28     OUT3     O Output Clock 3 positive.       29     OUT4b     O Output Clock 4 negative.       30     OUT4     O Output Clock 4 positive.       31     OUT5b     O Output Clock 5 negative.       32     OUT5     O Output Clock 5 positive.       33     OUT6b     O Output Clock 6 negative.       34     OUT6     O Output Clock 6 positive.       35     OUT7b     O Output Clock 7 negative.	22	OUT1b	0	Output Clock 1 negative.
25 OUT2b O Output Clock 2 negative.  26 OUT2 O Output Clock 2 positive.  27 OUT3b O Output Clock 3 negative.  28 OUT3 O Output Clock 3 positive.  29 OUT4b O Output Clock 4 negative.  30 OUT4 O Output Clock 4 positive.  31 OUT5b O Output Clock 5 negative.  32 OUT5 O Output Clock 5 positive.  33 OUT6b O Output Clock 6 negative.  34 OUT6 O Output Clock 6 positive.  35 OUT7b O Output Clock 7 negative.	23	OUT1	0	Output Clock 1 positive.
26 OUT2 O Output Clock 2 positive.  27 OUT3b O Output Clock 3 negative.  28 OUT3 O Output Clock 3 positive.  29 OUT4b O Output Clock 4 negative.  30 OUT4 O Output Clock 4 positive.  31 OUT5b O Output Clock 5 negative.  32 OUT5 O Output Clock 5 positive.  33 OUT6b O Output Clock 6 negative.  34 OUT6 O Output Clock 6 positive.  35 OUT7b O Output Clock 7 negative.	24	VDDO2	Power	Power supply for output bank 2 and FOD 0. See Table 8 for supported voltages.
27       OUT3b       O       Output Clock 3 negative.         28       OUT3       O       Output Clock 3 positive.         29       OUT4b       O       Output Clock 4 negative.         30       OUT4       O       Output Clock 4 positive.         31       OUT5b       O       Output Clock 5 negative.         32       OUT5       O       Output Clock 5 positive.         33       OUT6b       O       Output Clock 6 negative.         34       OUT6       O       Output Clock 6 positive.         35       OUT7b       O       Output Clock 7 negative.	25	OUT2b	0	Output Clock 2 negative.
28 OUT3 O Output Clock 3 positive.  29 OUT4b O Output Clock 4 negative.  30 OUT4 O Output Clock 4 positive.  31 OUT5b O Output Clock 5 negative.  32 OUT5 O Output Clock 5 positive.  33 OUT6b O Output Clock 6 negative.  34 OUT6 O Output Clock 6 positive.  35 OUT7b O Output Clock 7 negative.	26	OUT2	0	Output Clock 2 positive.
29 OUT4b O Output Clock 4 negative.  30 OUT4 O Output Clock 4 positive.  31 OUT5b O Output Clock 5 negative.  32 OUT5 O Output Clock 5 positive.  33 OUT6b O Output Clock 6 negative.  34 OUT6 O Output Clock 6 positive.  35 OUT7b O Output Clock 7 negative.	27	OUT3b	0	Output Clock 3 negative.
30 OUT4 O Output Clock 4 positive.  31 OUT5b O Output Clock 5 negative.  32 OUT5 O Output Clock 5 positive.  33 OUT6b O Output Clock 6 negative.  34 OUT6 O Output Clock 6 positive.  35 OUT7b O Output Clock 7 negative.	28	OUT3	0	Output Clock 3 positive.
31 OUT5b O Output Clock 5 negative.  32 OUT5 O Output Clock 5 positive.  33 OUT6b O Output Clock 6 negative.  34 OUT6 O Output Clock 6 positive.  35 OUT7b O Output Clock 7 negative.	29	OUT4b	0	Output Clock 4 negative.
32 OUT5 O Output Clock 5 positive.  33 OUT6b O Output Clock 6 negative.  34 OUT6 O Output Clock 6 positive.  35 OUT7b O Output Clock 7 negative.	30	OUT4	0	Output Clock 4 positive.
33 OUT6b O Output Clock 6 negative.  34 OUT6 O Output Clock 6 positive.  35 OUT7b O Output Clock 7 negative.	31	OUT5b	0	Output Clock 5 negative.
34 OUT6 O Output Clock 6 positive.  35 OUT7b O Output Clock 7 negative.	32	OUT5	0	Output Clock 5 positive.
35 OUT7b O Output Clock 7 negative.	33	OUT6b	0	Output Clock 6 negative.
	34	OUT6	0	Output Clock 6 positive.
36 OUT7 O Output Clock 7 positive.	35	OUT7b	0	Output Clock 7 negative.
	36	OUT7	0	Output Clock 7 positive.

Table 1. RCxxx12B Pin Descriptions (Cont.)

Number	Name	Туре	Description
37	VDDO3	Power	Power supply for output bank 3 and FOD 1. See Table 8 for supported voltages.
38	OUT8b	0	Output Clock 8 negative.
39	OUT8	0	Output Clock 8 positive.
40	OUT9b	0	Output Clock 9 negative.
41	OUT9	0	Output Clock 9 positive.
42	VDDO4	Power	Power supply for output bank 4 and FOD 2. See Table 8 for supported voltages.
43	VDDO5	Power	Power supply for output bank 5 and IOD 2. See Table 8 for supported voltages.
44	OUT10b	0	Output Clock 10 negative.
45	OUT10	0	Output Clock 10 positive.
46	OUT11b	0	Output Clock 11 negative.
47	OUT11	0	Output Clock 11 positive.
48	VDDO6	Power	Supply voltage for output bank 6 and IOD 3. See Table 8 for supported voltages.
EPAD	GND	Power	Ground. ePad must be connected to ground before any VDD is applied.

### 1.3 Pin Assignments – RCxxx12BQ (Top View)



#### 1.4 Pin Descriptions - RCxxx12BQ

Table 2. RCxxx12B Pin Descriptions

Number	Name	Туре	Description
1	VDDA	Power	Analog power supply. See Table 8 for supported voltages.
2	DNC	N/A	Do not connect. This pin should have no stubs.
3	DNC	N/A	Do not connect. This pin should have no stubs.
4	VDDX	Power	Crystal oscillator power supply. See Table 8 for supported voltages.
5	CLKIN0_GPI0	I	Differential clock positive input / CMOS single-ended reference clock input or general purpose input pin GPI0.
6	CLKIN0b_GPI1	I	Differential clock negative input / CMOS single-ended reference clock input or general purpose input pin GPI1.
7	VDDR	Power	CLKIN (receiver) power supply. See Table 8 for supported voltages.
8	CLKIN1_GPI2	I	Differential clock positive input / CMOS single-ended reference clock input or general purpose input pin GPI2.
9	CLKIN1b_GPI3	I	Differential clock negative input / CMOS single-ended reference clock input or general purpose input pin GPI3.

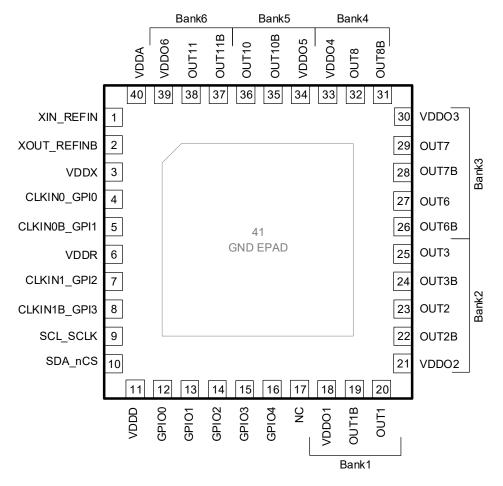
Table 2. RCxxx12B Pin Descriptions (Cont.)

Number	Name	Туре	Description
10	SCL_SCLK	I	I2C Mode: I <sup>2</sup> C interface bi-directional clock. SPI Mode: Serial Clock This pin is 3.3V tolerant.
11	SDA_nCS	1	I2C Mode: I <sup>2</sup> C interface bi-directional data in open-drain mode. SPI Mode: Chip Select (active low)  This pin is 3.3V tolerant.
12	VDDD	Power	Digital core and GPIO power supply. See Table 8 for supported voltages. When programming the OTP, this supply must be 2.5V or 3.3V.
13	GPIO0	I/O	General purpose input/output.  3-level logic input during power-up and CMOS level logic after unless set to 3-level.
14	GPIO1	I/O	General purpose input/output.  3-level logic input during power-up and CMOS level logic after unless set to 3-level.
15	GPIO2	I/O	General purpose input/output.  3-level logic input during power-up and CMOS level logic after unless set to 3-level.
16	GPIO3	I/O	General purpose input/output.
17	GPIO4	I/O	General purpose input/output.
18	nOUT0b	0	Output Clock 0 negative.
19	OUT0	0	Output Clock 0 positive.
20	VDD00	Power	Power supply for output bank 0 and IOD 0. See Table 8 for supported voltages.
21	VDDO1	Power	Power supply for output bank 1 and IOD 1. See Table 8 for supported voltages.
22	OUT1b	0	Output Clock 1 negative.
23	OUT1	0	Output Clock 1 positive.
24	VDDO2	Power	Power supply for output bank 2 and FOD 0. See Table 8 for supported voltages.
25	OUT2b	0	Output Clock 2 negative.
26	OUT2	0	Output Clock 2 positive.
27	OUT3b	0	Output Clock 3 negative.
28	OUT3	0	Output Clock 3 positive.
29	OUT4b	0	Output Clock 4 negative.
30	OUT4	0	Output Clock 4 positive.
31	OUT5b	0	Output Clock 5 negative.
32	OUT5	0	Output Clock 5 positive.
33	OUT6b	0	Output Clock 6 negative.
34	OUT6	0	Output Clock 6 positive.
35	OUT7b	0	Output Clock 7 negative.
36	OUT7	0	Output Clock 7 positive.
37	VDDO3	Power	Power supply for output bank 3 and FOD 1. See Table 8 for supported voltages.
38	OUT8b	0	Output Clock 8 negative.
39	OUT8	0	Output Clock 8 positive.
40	OUT9b	0	Output Clock 9 negative.

#### Table 2. RCxxx12B Pin Descriptions (Cont.)

Number	Name	Туре	Description
41	OUT9	0	Output Clock 9 positive.
42	VDDO4	Power	Power supply for output bank 4 and FOD 2. See Table 8 for supported voltages.
43	VDDO5	Power	Power supply for output bank 5 and IOD 2. See Table 8 for supported voltages.
44	OUT10b	0	Output Clock 10 negative.
45	OUT10	0	Output Clock 10 positive.
46	OUT11b	0	Output Clock 11 negative.
47	OUT11	0	Output Clock 11 positive.
48	VDDO6	Power	Supply voltage for output bank 6 and IOD 3. See Table 8 for supported voltages.
EPAD	GND	Power	Ground. ePad must be connected to ground before any VDD is applied.

## 1.5 Pin Assignments – RCxxx08B (Top View)



#### 1.6 Pin Descriptions - RCxxx08B

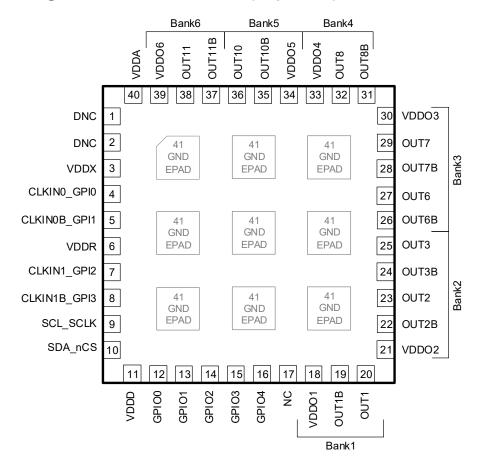
Table 3. RCxxx08B Pin Descriptions

Number	Name	Туре	Description
1	XIN_REFIN	I	Crystal Input or differential reference clock positive input / CMOS single-ended reference clock input.
2	XOUT_REFINb	I/O	Crystal Output or differential reference clock negative input.  This pin should be connected to a crystal. If an oscillator is connected to XIN_REFIN, then this pin must be left unconnected.
3	VDDX	Power	Crystal oscillator power supply. See Table 8 for supported voltages.
4	CLKIN0_GPI0	I	differential clock positive input / CMOS single-ended reference clock input or general purpose input pin GPI0.
5	CLKIN0b_GPI1	I	differential clock negative input / CMOS single-ended reference clock input or general purpose input pin GPI1.
6	VDDR	Power	CLKIN (receiver) power supply. See Table 8 for supported voltages.
7	CLKIN1_GPI2	I	Differential clock positive input / CMOS single-ended reference clock input or general purpose input pin GPI2.
8	CLKIN1b_GPI3	I	Differential clock negative input / CMOS single-ended reference clock input or general purpose input pin GPI3.
9	SCL_SCLK	I	I2C Mode: I <sup>2</sup> C interface bi-directional clock.  SPI Mode: Serial Clock  This pin is 3.3V tolerant.

Table 3. RCxxx08B Pin Descriptions (Cont.)

Number	Name	Туре	Description
10	SDA_nCS	I/O	I2C Mode: I <sup>2</sup> C interface bi-directional data in open-drain mode.  SPI Mode: Chip Select (active low)  This pin is 3.3V tolerant.
11	VDDD	Power	Digital core and GPIO power supply. See Table 8 for supported voltages. When programming the OTP, this supply must be 2.5V or 3.3V.
12	GPIO0	I/O	General purpose input/output.  3-level logic input during power-up and CMOS level logic after unless set to 3-level.
13	GPIO1	I/O	General purpose input/output.  3-level logic input during power-up and CMOS level logic after unless set to 3-level.
14	GPIO2	I/O	General purpose input/output.  3-level logic input during power-up and CMOS level logic after unless set to 3-level.
15	GPIO3	I/O	General purpose input/output.
16	GPIO4	I/O	General purpose input/output.
17	NC	I	Not connected.
18	VDDO1	Power	Power supply for output bank 1 and IOD 1. See Table 8 for supported voltages.
19	OUT1b	0	Output Clock 1 negative.
20	OUT1	0	Output Clock 1 positive
21	VDDO2	Power	Power supply for output bank 2 and FOD 0. See Table 8 for supported voltages.
22	OUT2b	0	Output Clock 2 negative.
23	OUT2	0	Output Clock 2 positive.
24	OUT3b	0	Output Clock 3 negative.
25	OUT3	0	Output Clock 3 positive.
26	OUT6b	0	Output Clock 6 negative.
27	OUT6	0	Output Clock 6 positive.
28	OUT7b	0	Output Clock 7 negative.
29	OUT7	0	Output Clock 7 positive.
30	VDDO3	Power	Power supply for output bank 3 and FOD 1. See Table 8 for supported voltages.
31	OUT8b	0	Output Clock 8 negative.
32	OUT8	0	Output Clock 8 positive.
33	VDDO4	Power	Power supply for output bank 4 and FOD 2. See Table 8 for supported voltages.
34	VDDO5	Power	Power supply for output bank 5 and IOD 2. See Table 8 for supported voltages.
35	OUT10b	0	Output Clock 10 negative.
36	OUT10	0	Output Clock 10 positive.
37	OUT11b	0	Output Clock 11 negative.
38	OUT11	0	Output Clock 11 positive.
39	VDD06	Power	Supply voltage for output bank 6 and IOD 3. See Table 8 for supported voltages.
40	VDDA	Power	Analog power supply. See Table 8 for supported voltages.
EPAD	GND	Power	Ground. ePad must be connected to ground before any VDD is applied.

### 1.7 Pin Assignments – RCxxx08BQ (Top View)



#### 1.8 Pin Descriptions - RCxxx08BQ

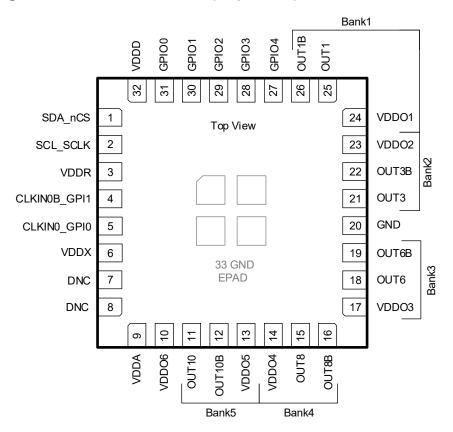
Table 4. RCxxx08BQ Pin Descriptions

Number	Name	Туре	Description
1	DNC	N/A	Do not connect. This pin should have no stubs.
2	DNC	N/A	Do not connect. This pin should have no stubs.
3	VDDX	Power	Crystal oscillator power supply. See Table 8 for supported voltages.
4	CLKIN0_GPI0	I	Differential clock positive input / CMOS single-ended reference clock input or general purpose input pin GPI0.
5	CLKIN0b_GPI1	I	Differential clock negative input / CMOS single-ended reference clock input or general purpose input pin GPI1.
6	VDDR	Power	CLKIN (receiver) power supply. See Table 8 for supported voltages.
7	CLKIN1_GPI2	I	Differential clock positive input / CMOS single-ended reference clock input or general purpose input pin GPI2.
8	CLKIN1b_GPI3	I	Differential clock negative input / CMOS single-ended reference clock input or general purpose input pin GPI3.
9	SCL_SCLK	I	I2C Mode: I <sup>2</sup> C interface bi-directional clock. SPI Mode: Serial Clock This pin is 3.3V tolerant.
10	SDA_nCS	I/O	I2C Mode: I <sup>2</sup> C interface bi-directional data in open-drain mode.  SPI Mode: Chip Select (active low)  This pin is 3.3V tolerant.

Table 4. RCxxx08BQ Pin Descriptions (Cont.)

Number	Name	Туре	Description
11	VDDD	Power	Digital core and GPIO power supply. See Table 8 for supported voltages. When programming the OTP, this supply must be 2.5V or 3.3V.
12	GPIO0	I/O	General purpose input/output.
12		"0	3-level logic input during power-up and CMOS level logic after unless set to 3-level.
13	GPIO1	I/O	General purpose input/output.  3-level logic input during power-up and CMOS level logic after unless set to 3-level.
14	GPIO2	I/O	General purpose input/output.  3-level logic input during power-up and CMOS level logic after unless set to 3-level.
15	GPIO3	I/O	General purpose input/output.
16	GPIO4	I/O	General purpose input/output.
17	NC	I	Not connected.
18	VDD01	Power	Power supply for output bank 1 and IOD 1. See Table 8 for supported voltages.
19	OUT1b	0	Output Clock 1 negative.
20	OUT1	0	Output Clock 1 positive
21	VDDO2	Power	Power supply for output bank 2 and FOD 0. See Table 8 for supported voltages.
22	OUT2b	0	Output Clock 2 negative.
23	OUT2	0	Output Clock 2 positive.
24	OUT3b	0	Output Clock 3 negative.
25	OUT3	0	Output Clock 3 positive.
26	OUT6b	0	Output Clock 6 negative.
27	OUT6	0	Output Clock 6 positive.
28	OUT7b	0	Output Clock 7 negative.
29	OUT7	0	Output Clock 7 positive.
30	VDDO3	Power	Power supply for output bank 3 and FOD 1. See Table 8 for supported voltages.
31	OUT8b	0	Output Clock 8 negative.
32	OUT8	0	Output Clock 8 positive.
33	VDDO4	Power	Power supply for output bank 4 and FOD 2. See Table 8 for supported voltages.
34	VDDO5	Power	Power supply for output bank 5 and IOD 2. See Table 8 for supported voltages.
35	OUT10b	0	Output Clock 10 negative.
36	OUT10	0	Output Clock 10 positive.
37	OUT11b	0	Output Clock 11 negative.
38	OUT11	0	Output Clock 11 positive.
39	VDDO6	Power	Supply voltage for output bank 6 and IOD 3. See Table 8 for supported voltages.
40	VDDA	Power	Analog power supply. See Table 8 for supported voltages.
EPAD	GND	Power	Ground. ePad must be connected to ground before any VDD is applied.

## 1.9 Pin Assignments – RCxxx05BQ (Top View)



#### 1.10 Pin Descriptions - RCxxx05BQ

Table 5. RCxxx05BQ Pin Descriptions

Number	Name	Туре	Description
1	SDA_nCS	I/O	I2C Mode: I <sup>2</sup> C interface bi-directional data in open-drain mode.  SPI Mode: Chip Select (active low)  This pin is 3.3V tolerant.
2	SCL_SCLK	I	I2C Mode: I <sup>2</sup> C interface bi-directional clock. SPI Mode: Serial Clock This pin is 3.3V tolerant.
3	VDDR	Power	CLKIN (receiver) power supply. See Table 8 for supported voltages.
4	CLKIN0b_GPI1	I	Differential clock negative input / CMOS single-ended reference clock input or general purpose input pin GPI1
5	CLKIN0_GPI0	I	Differential clock positive input / CMOS single-ended reference clock input or general purpose input pin GPI0
6	VDDX	Power	Crystal oscillator power supply. See Table 8 for supported voltages.
7	DNC	NA	Do not connect. This pin should have no stubs.
8	DNC	NA	Do not connect. This pin should have no stubs.
9	VDDA	Power	Analog power supply. See Table 8 for supported voltages.
10	VDDO6	Power	Supply voltage for output bank 6 and IOD 3. See Table 8 for supported voltages.
11	OUT10	0	Output Clock 10 positive.
12	OUT10b	0	Output Clock 10 negative.

Table 5. RCxxx05BQ Pin Descriptions (Cont.)

Number	Name	Туре	Description			
13	VDDO5	Power	Power supply for output bank 5 and IOD 2. See Table 8 for supported voltages.			
14	VDDO4	Power	Power supply for output bank 4 and FOD 2. See Table 8 for supported voltages.			
15	OUT8	0	Output Clock 8 positive.			
16	OUT8b	0	Output Clock 8 negative.			
17	VDDO3	Power	Power supply for output bank 3 and FOD 1. See Table 8 for supported voltages.			
18	OUT6	0	Output Clock 6 positive.			
19	OUT6b	0	Output Clock 6 negative.			
20	GND	Power	Ground			
21	OUT3	0	Output Clock 3 positive.			
22	OUT3b	0	Output Clock 3 negative.			
23	VDDO2	Power	Power supply for output bank 2 and FOD 0. See Table 8 for supported voltages.			
24	VDDO1	Power	Power supply for output bank 1 and IOD 1. See Table 8 for supported voltages.			
25	OUT1	0	Output Clock 1 positive			
26	OUT1b	0	Output Clock 1 negative.			
27	GPIO4	I/O	General purpose input/output			
28	GPIO3	I/O	General purpose input/output			
29	GPIO2	I/O	General purpose input/output  3-level logic input during power-up and CMOS level logic after unless set to 3-level.			
30	GPIO1	I/O	General purpose input/output  3-level logic input during power-up and CMOS level logic after unless set to 3-level.			
31	GPIO0	I/O	General purpose input/output  3-level logic input during power-up and CMOS level logic after unless set to 3-level.			
32	VDDD	Power	Digital core and GPIO power supply. See Table 8 for supported voltages. When programming the OTP, this supply must be 2.5V or 3.3V.			
EPAD	GND	Power	Ground. ePad must be connected to ground before any VDD is applied.			

#### 1.11 Pin Characteristics

**Table 6. Pin Characteristics** 

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Unit
		CLKIN[1:0], CLKIN[1:0]b, GPI[0:3]	-	2	-	
		SCL_SCLK, SDA_nCS	-	3	-	
C <sub>IN</sub>	Input Capacitance	XIN_REFIN [1]	-	5	-	pF
		XOUT_REFINb [1]	-	4	-	
		GPIO[0:4]	-	5	-	
R <sub>PULLUP</sub>	Input Pull-Up Resistor	All pins with internal pull up capability	-	52.6	-	kΩ
R <sub>PULLDOWN</sub>	Input Pull-Down Resistor	All pins with internal pull down capability	-	52.6	-	
	Single-ended LP-HCSL Output Impedance	$50\Omega$ single-ended (100 $\Omega$ differential).	-	51	-	40 to 60Ω
Z <sub>OUTDC</sub>		42.5Ω single-ended (85Ω differential).	-	44	-	34 to 51Ω
2001DC		VDDO = 3.3V	-	17.3	-	
	LVCMOS Output Impedance	VDDO = 2.5V.	-	19.5	-	Ω
		VDDO = 1.8V	-	17.6	-	

<sup>1.</sup> When used as clock input.

## 2. Specifications

The absolute maximum ratings are stress ratings only. Stresses greater than those listed below can cause permanent damage to the device. Functional operation of the RC210xxB at absolute maximum ratings is not implied. Exposure to absolute maximum rating conditions may affect device reliability.

#### 2.1 Absolute Maximum Ratings

**Table 7. Absolute Maximum Ratings** 

Symbol	Parameter	Conditions	Minimum	Maximum	Unit
$V_{DD}$	Supply Voltage with respect to Ground	Any VDD pin	-0.5	3.63	V
		XIN_REFIN, XOUT_REFINb [2]	-0.5	V <sub>DD</sub> + 0.3	V
$V_{IN}$	Input Voltage <sup>[1]</sup>	CLKIN[1:0]_GPI[1:0], CLKIN[1:0]b_GPI[3:2]	-0.5	V <sub>DD</sub> + 0.3	V
		GPIO[4:0] used as inputs	-0.5	V <sub>DD</sub> + 0.3	V
		SCL_SCLK, SDA_nCS	-0.5	3.63	V
I <sub>IN</sub>	Input Current	CLKIN[1:0]_GPI[1:0], CLKIN[1:0]b_GPI[3:2]	-	±50	mA
		OUT[11:0], OUT[11:0]b	-	30	mA
1	Output Current - Continuous	GPIO[4:0] used as outputs, SDA_nCS	-	25	mA
I <sub>OUT</sub>		OUT[11:0], OUT[11:0]b	-	60	mA
	Output Current - Surge	GPIO[4:0] used as outputs, SDA_nCS	-	50	mA
$T_J$	Maximum Junction Temperature		-	150	°C
T <sub>S</sub>	Storage Temperature	Storage Temperature	-65	150	°C
ESD	Human Body Model	JESD22-A114 (JS-001) Classification	-	2000	V
ESD	Charged Device Model	JESD22-C101 Classification	-	500	V

<sup>1.</sup> VDD refers to the VDD pin that supplies the particular input. To determine to which VDD pin the specification applies, see Table 44.

<sup>2.</sup> This limit only applies when XIN\_REFIN/XOUT\_REFINb are configured as an "Input Buffer" for use with an external oscillator. No limit is implied when connected directly to a crystal.

## 2.2 Recommended Operating Conditions

Table 8. Recommended Operating Conditions [1][2]

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Unit
$T_J$	Maximum Junction Temperature		-	-	125	°C
T <sub>A</sub>	Ambient Operating temperature		-40	-	85	°C
	Supply Voltage with respect to Ground	Any VDD pin, 1.8V supply	1.71	1.8	1.89	V
$V_{DDx}$		Any VDD pin, 2.5V supply	2.375	2.5	2.625	V
		Any VDD pin, 3.3V supply	3.135	3.3	3.465	٧
t <sub>PU</sub>	Power-up time for all VDDs to reach minimum specified voltage.	Power ramps must be monotonic. For more considerations, see Application Information.	0.2	-	5	ms

<sup>1.</sup> All electrical characteristics are specified over Recommended Operating Conditions unless noted otherwise.

#### 2.3 Electrical Characteristics

Table 9. PCle Refclk Jitter for VDDO = 1.8V [1][2]

Symbol	Parameter	Conditions	Typical	Maximum	PCle Limit	Unit
t <sub>jphPCleG1-CC</sub>		PCle Gen 1 (2.5 GT/s)	4330	8622	86,000	fs pk-pk
4	PCIe Refclk Jitter in Clock	PCle Gen 2 Hi Band (5 GT/s)	265	547	3000	
<sup>t</sup> jphPCIeG2-CC	Generator Mode	PCle Gen 2 Lo Band (5 GT/s)	76	210	3100	
t <sub>jphPCleG3-CC</sub>	(Common Clocked	PCle Gen 3 (8 GT/s)	126	246	1000	fs RMS
t <sub>jphPCleG4-CC</sub>	Architecture, SSC = 0%, -0.3%, -0.5%)	PCIe Gen 4 (16 GT/s) [3][4]	126	246	500	IS KIVIS
t <sub>jphPCleG5-CC</sub>	0.070, 0.070, 0.070)	PCIe Gen 5 (32 GT/s) [3][5]	49	95	150	
t <sub>jphPCle6-CC</sub>		PCIe Gen 6 (64 GT/s) [3][6]	29	59	100	
t <sub>jphPCleG2-SRIS</sub>	PCIe Refclk Jitter Clock Generator Mode (SRIS Architecture,	PCle Gen 2 (5 GT/s)	1342	1474	– N/A <sup>[7]</sup>	fs RMS
t <sub>jphPCleG3-SRIS</sub>		PCle Gen 3 (8 GT/s)	313	355		
t <sub>jphPCleG4-SRIS</sub>	SSC = 0.0% or -0.5%)	PCle Gen 4 (16 GT/s)	137	178		
t <sub>jphPCleG5-SRIS</sub>	PCIe Refclk Jitter Clock	PCle Gen 5 (32 GT/s)	104	146		
t <sub>jphPCleG6-SRIS</sub>	Generator Mode (SRIS Architecture, SSC =0.0% or -0.3%)	PCle Gen 6 (64 GT/s)	115	174		
t <sub>jphPCleG2-SRNS</sub>		PCle Gen 2 (5 GT/s)	137	277		
t <sub>jphPCleG3-SRNS</sub>	PCIe Refclk Jitter in Clock	PCle Gen 3 (8 GT/s)	61	131		
t <sub>jphPCleG4-SRNS</sub>	Generator Mode (SRNS Architecture, SSC = 0%)	PCle Gen 4 (16 GT/s)	61	131	N/A <sup>[7]</sup>	fs RMS
t <sub>jphPCleG5-SRNS</sub>		PCle Gen 5 (32 GT/s)	24	52		
t <sub>jphPCleG6-SRNS</sub>		PCle Gen 6 (64 GT/s)	15	31		

<sup>2.</sup> All conditions in this table must be met to guarantee device functionality and performance.

Table 9. PCle Refclk Jitter for VDDO = 1.8V [1][2] (Cont.)

Symbol	Parameter	Conditions	Typical	Maximum	PCle Limit	Unit
t <sub>jphPCleG1-CC</sub>		PCle Gen 1 (2.5 GT/s)	3242	10190		fs pk-pk
4	Additive PCIe Refclk Jitter in Fan-out Buffer Mode (CC Architecture, SSC = 0%, -0.3%, -0.5%)  PCIe Refclk Jitter Clock Generator Mode (SRIS Architecture, SSC = 0.0% or -0.5%)  PCIe Refclk Jitter Clock Generator Mode (SRIS Architecture, SSC = 0.0% or -0.3%)  Additive PCIe Refclk Jitter in Fan-out Buffer Mode	PCle Gen 2 Hi Band (5 GT/s)	201	656		
<sup>t</sup> jphPCleG2-CC		PCle Gen 2 Lo Band (5 GT/s)	44	160		
t <sub>jphPCleG3-CC</sub>		PCle Gen 3 (8 GT/s)	88	268	N/A <sup>[7][8]</sup>	fs RMS
t <sub>jphPCleG4-CC</sub>	,	PCle Gen 4 (16 GT/s) [3][4]	88	268		15 KIVIO
t <sub>jphPCleG5-CC</sub>		PCIe Gen 5 (32 GT/s) [3][5]	34	102		
t <sub>jphPCle6-CC</sub>	-	PCle Gen 6 (64 GT/s) [3][6]	22	67		
t <sub>jphPCleG2-SRIS</sub>	Generator Mode	PCle Gen 2 (5 GT/s)	252	833	N/A [7][8]	fs RMS
t <sub>jphPCleG3-SRIS</sub>		PCle Gen 3 (8 GT/s)	65	210		
t <sub>jphPCleG4-SRIS</sub>	,	PCIe Gen 4 (16 GT/s)	67	217		
t <sub>jphPCleG5-SRIS</sub>		PCle Gen 5 (32 GT/s)	58	192		
t <sub>jphPCleG6-SRIS</sub>	(SRIS Architecture,	PCIe Gen 6 (64 GT/s)	76	257		
t <sub>jphPCleG2-SRNS</sub>		PCle Gen 2 (5 GT/s)	244	843		
t <sub>jphPCleG3-SRNS</sub>	Fan-out Buffer Mode	PCle Gen 3 (8 GT/s)	63	212	N/A <sup>[7][8]</sup>	fs RMS
t <sub>jphPCleG4-SRNS</sub>		PCIe Gen 4 (16 GT/s)	65	219		
t <sub>jphPCleG5-SRNS</sub>		PCIe Gen 5 (32 GT/s)	57	194		
t <sub>jphPCleG6-SRNS</sub>		PCIe Gen 6 (64 GT/s)	74	264	-	

- 1. The Refclk jitter is measured after applying the filter functions found in *PCI Express Base Specification 6.0*, *Revision 0.9*. See the Test Loads section of the data sheet for the exact measurement setup. The worst case results for each data rate are summarized in this table. Equipment noise is removed from all measurements.
- 2. Jitter measurements should be made with a capture of at least 100,000 clock cycles captured by a real-time oscilloscope (RTO) with a sample rate of 20 GS/s or greater. Broadband oscilloscope noise must be minimized in the measurement. The measured PP jitter is used (no extrapolation) for RTO measurements. Alternately Jitter measurements may be used with a Phase Noise Analyzer (PNA) extending (flat) and integrating and folding the frequency content up to an offset from the carrier frequency of at least 200 MHz (at 300 MHz absolute frequency) below the Nyquist frequency. For PNA measurements for the 2.5 GT/s data rate, the RMS jitter is converted to peak-to-peak jitter using a multiplication factor of 8.83.
- 3. SSC spurs from the fundamental and harmonics are removed up to a cutoff frequency of 2 MHz taking care to minimize removal of any non-SSC content.
- 4. Note that 0.7 ps RMS is to be used in channel simulations to account for additional noise in a real system.
- 5. Note that 0.25 ps RMS is to be used in channel simulations to account for additional noise in a real system.
- 6. Note that 0.15 ps RMS is to be used in channel simulations to account for additional noise in a real system.
- 7. The PCI Express Base Specification 6.0, Revision 0.9 provides the filters necessary to calculate SRIS and SRNS jitter values; it does not provide specification limits, hence the N/A in the Limit column. SRIS and SRNS values are informative only. A common practice is to split the common clock budget in half. For 16GT/s data rates and above, the user must choose whether to use the output jitter specification, or the input jitter specification, which includes an allocation for the jitter added by the channel. Using 32GT/s, the Refclk jitter budget is 150fs RMS. One half of the Refclk jitter budget is 106fs RMS. At the clock input, the system must deliver 250fs RMS. One half of this value is 177fs RMS. If the clock is placed next to the PCIe device in an SRIS system, the channel is very short and the user may choose to use this more relaxed value as the jitter limit.
- 8. The RMS sum of the source jitter and the additive jitter must be less than the jitter specification listed for the clock generator operating mode.

Table 10. PCle Refclk Jitter for VDDO = 2.5V [1][2]

Symbol	Parameter	Conditions	Typical	Maximum	PCIe Limit	Unit
t <sub>jphPCleG1-CC</sub>		PCle Gen 1 (2.5 GT/s)	4054	5248	86,000	fs pk-pk
1	PCIe Refclk Jitter in Clock Generator Mode (Common Clocked	PCle Gen 2 Hi Band (5 GT/s)	241	322	3000	
t <sub>jphPCleG2-CC</sub>		PCle Gen 2 Lo Band (5 GT/s)	67	142	3100	fs RMS
t <sub>jphPCleG3-CC</sub>		PCle Gen 3 (8 GT/s)	118	150	1000	
t <sub>jphPCleG4-CC</sub>	Architecture, SSC = 0%, - 0.3%, -0.5%)	PCle Gen 4 (16 GT/s) [3][4]	118	150	500	
t <sub>jphPCleG5-CC</sub>	0.370, -0.370)	PCle Gen 5 (32 GT/s) [3][5]	46	60	150	
t <sub>jphPCle6-CC</sub>		PCle Gen 6 (64 GT/s) [3][6]	28	35	100	
t <sub>jphPCleG2-SRIS</sub>	PCIe Refclk Jitter Clock	PCle Gen 2 (5 GT/s)	1328	1366		
t <sub>jphPCleG3-SRIS</sub>	(SRIS Architecture, SSC = 0.0% or -0.5%)  PCIe Refclk Jitter Clock Generator Mode (SRIS Architecture, SSC = 0.0% or -0.3%)	PCle Gen 3 (8 GT/s)	309	323	_	
t <sub>jphPCleG4-SRIS</sub>		PCle Gen 4 (16 GT/s)	133	142		
t <sub>iphPCleG5-SRIS</sub>		PCle Gen 5 (32 GT/s)	99	115	N/A <sup>[7]</sup>	fs RMS
tjphPCleG6-SRIS		PCle Gen 6 (64 GT/s)	106	132	-	
t <sub>jphPCleG2-SRNS</sub>		PCle Gen 2 (5 GT/s)	125	215		
t <sub>iphPCleG3-SRNS</sub>	PCIe Refclk Jitter in Clock Generator Mode (SRNS Architecture, SSC = 0%)	PCle Gen 3 (8 GT/s)	55	81	N/A [7]	
t <sub>jphPCleG4-SRNS</sub>		PCle Gen 4 (16 GT/s)	55	81		fs RMS
t <sub>iphPCleG5-SRNS</sub>		PCle Gen 5 (32 GT/s)	21	33		
t <sub>jphPCleG6-SRNS</sub>		PCle Gen 6 (64 GT/s)	13	19		
t <sub>jphPCleG1-CC</sub>		PCle Gen 1 (2.5 GT/s)	2032	5139		fs pk-pk
<u>.</u>		PCle Gen 2 Hi Band (5 GT/s)	122	277		
<sup>t</sup> jphPCleG2-CC	Additive PCIe Refclk Jitter	PCle Gen 2 Lo Band (5 GT/s)	34	65		
t <sub>jphPCleG3-CC</sub>	Additive PCIe Refclk Jitter F	PCle Gen 3 (8 GT/s)	57	137	N/A [7][8]	
t <sub>jphPCleG4-CC</sub>	0%, -0.3%, -0.5%)	PCle Gen 4 (16 GT/s) [3][4]	55	137		fs RMS
t <sub>jphPCleG5-CC</sub>		PCle Gen 5 (32 GT/s) [3][5]	23	56		
t <sub>jphPCle6-CC</sub>		PCle Gen 6 (64 GT/s) [3][6]	14	33		
t <sub>jphPCleG2-SRIS</sub>	Additive PCle Refclk Jitter	PCle Gen 2 (5 GT/s)	152	310		
t <sub>jphPCleG3-SRIS</sub>	in Fan-out Buffer Mode (SRIS Architecture, SSC =	PCle Gen 3 (8 GT/s)	40	84		
t <sub>jphPCleG4-SRIS</sub>	0.0% or -0.5%)	PCle Gen 4 (16 GT/s)	41	86	[7][0]	
t <sub>jphPCleG5-SRIS</sub>	Additive PCIe Refclk Jitter in Fan-out Buffer Mode	PCle Gen 5 (32 GT/s)	36	94	N/A <sup>[7][8]</sup>	fs RMS
t <sub>jphPCleG6-SRIS</sub>	(SRIS Architecture, SSC = 0.0% or -0.3%)	PCIe Gen 6 (64 GT/s)	46	108		
t <sub>jphPCleG2-SRNS</sub>		PCle Gen 2 (5 GT/s)	164	348		
t <sub>jphPCleG3-SRNS</sub>	Additive PCIe Refclk Jitter	PCle Gen 3 (8 GT/s)	43	94		
t <sub>jphPCleG4-SRNS</sub>	in Fan-out Buffer Mode	PCle Gen 4 (16 GT/s)	45	97	N/A [7][8]	fs RMS
t <sub>jphPCleG5-SRNS</sub>	(SRNS Architecture, SSC = 0%)	PCle Gen 5 (32 GT/s)	39	102		
t <sub>iphPCleG6-SRNS</sub>		PCle Gen 6 (64 GT/s)	49	116	1	

<sup>1.</sup> The Refclk jitter is measured after applying the filter functions found in *PCI Express Base Specification 6.0, Revision 0.9*. See the Test Loads section of the data sheet for the exact measurement setup. The worst case results for each data rate are summarized in this table. Equipment noise is removed from all measurements.



- 2. Jitter measurements should be made with a capture of at least 100,000 clock cycles captured by a real-time oscilloscope (RTO) with a sample rate of 20 GS/s or greater. Broadband oscilloscope noise must be minimized in the measurement. The measured PP jitter is used (no extrapolation) for RTO measurements. Alternately Jitter measurements may be used with a Phase Noise Analyzer (PNA) extending (flat) and integrating and folding the frequency content up to an offset from the carrier frequency of at least 200 MHz (at 300 MHz absolute frequency) below the Nyquist frequency. For PNA measurements for the 2.5 GT/s data rate, the RMS jitter is converted to peak-to-peak jitter using a multiplication factor of 8.83.
- 3. SSC spurs from the fundamental and harmonics are removed up to a cutoff frequency of 2 MHz taking care to minimize removal of any non-SSC content.
- 4. Note that 0.7 ps RMS is to be used in channel simulations to account for additional noise in a real system.
- 5. Note that 0.25 ps RMS is to be used in channel simulations to account for additional noise in a real system.
- 6. Note that 0.15 ps RMS is to be used in channel simulations to account for additional noise in a real system.
- 7. The PCI Express Base Specification 6.0, Revision 0.9 provides the filters necessary to calculate SRIS and SRNS jitter values; it does not provide specification limits, hence the N/A in the Limit column. SRIS and SRNS values are informative only. A common practice is to split the common clock budget in half. For 16GT/s data rates and above, the user must choose whether to use the output jitter specification, or the input jitter specification, which includes an allocation for the jitter added by the channel. Using 32GT/s, the Refclk jitter budget is 150fs RMS. One half of the Refclk jitter budget is 106fs RMS. At the clock input, the system must deliver 250fs RMS. One half of this value is 177fs RMS. If the clock is placed next to the PCIe device in an SRIS system, the channel is very short and the user may choose to use this more relaxed value as the jitter limit.
- 8. The RMS sum of the source jitter and the additive jitter must be less than the jitter specification listed for the clock generator operating mode.

Table 11. PCIe Refclk Jitter for VDDO = 3.3V [1][2]

Symbol	Parameter	Conditions	Typical	Maximum	PCIe Limit	Unit
t <sub>jphPCleG1-CC</sub>		PCle Gen 1 (2.5 GT/s)	4042	5554	86,000	fs pk-pk
	PCIe Refclk Jitter in Clock Generator Mode (Common Clocked	PCle Gen 2 Hi Band (5 GT/s)	241	332	3000	
<sup>t</sup> jphPCleG2-CC		PCle Gen 2 Lo Band (5 GT/s)	65	146	3100	
t <sub>jphPCleG3-CC</sub>		PCle Gen 3 (8 GT/s)	118	164	1000	fs RMS
t <sub>jphPCleG4-CC</sub>	Architecture, SSC = 0%, - 0.3%, -0.5%)	PCIe Gen 4 (16 GT/s) [3][4]	118	164	500	15 KIVIS
t <sub>jphPCleG5-CC</sub>	0.070, 0.070,	PCIe Gen 5 (32 GT/s) [3][5]	46	65	150	
t <sub>jphPCle6-CC</sub>		PCIe Gen 6 (64 GT/s) [3][6]	27	37	100	
t <sub>jphPCleG2-SRIS</sub>	PCIe Refclk Jitter Clock Generator Mode (SRIS Architecture,	PCle Gen 2 (5 GT/s)	1329	1392	N/A <sup>[7]</sup>	fs RMS
t <sub>jphPCleG3-SRIS</sub>		PCIe Gen 3 (8 GT/s)	309	328		
t <sub>jphPCleG4-SRIS</sub>	SSC = 0.0% or -0.5%)	PCIe Gen 4 (16 GT/s)	133	145		
t <sub>jphPCleG5-SRIS</sub>	PCIe Refclk Jitter Clock	PCIe Gen 5 (32 GT/s)	99	114		
t <sub>jphPCleG6-SRIS</sub>	Generator Mode (SRIS Architecture, SSC = 0.0% or -0.3%)	PCIe Gen 6 (64 GT/s)	106	132		
t <sub>jphPCleG2-SRNS</sub>		PCle Gen 2 (5 GT/s)	125	208		
t <sub>jphPCleG3-SRNS</sub>	PCIe Refclk Jitter in Clock	PCIe Gen 3 (8 GT/s)	56	81		fs RMS
t <sub>jphPCleG4-SRNS</sub>	Generator Mode (SRNS Architecture, SSC = 0%)	PCIe Gen 4 (16 GT/s)	56	81	N/A <sup>[7]</sup>	
t <sub>jphPCleG5-SRNS</sub>		PCle Gen 5 (32 GT/s)	22	32		
t <sub>jphPCleG6-SRNS</sub>		PCle Gen 6 (64 GT/s)	13	19		

Table 11. PCle Refclk Jitter for VDDO = 3.3V [1][2] (Cont.)

Symbol	Parameter	Conditions	Typical	Maximum	PCle Limit	Unit
t <sub>jphPCleG1-CC</sub>		PCle Gen 1 (2.5 GT/s)	2256	4829		fs pk-pk
4		PCle Gen 2 Hi Band (5 GT/s)	132	241		
<sup>t</sup> jphPCleG2-CC	Additive PCIe Refclk Jitter	PCle Gen 2 Lo Band (5 GT/s)	35	51		
t <sub>jphPCleG3-CC</sub>	in Fan-out Buffer Mode (CC Architecture, SSC =	PCle Gen 3 (8 GT/s)	63	122	N/A <sup>[7][8]</sup>	fs RMS
t <sub>jphPCleG4-CC</sub>	0%, -0.3%, -0.5%)	PCle Gen 4 (16 GT/s) [3][4]	63	122		IS KIVIS
t <sub>jphPCleG5-CC</sub>		PCle Gen 5 (32 GT/s) [3][5]	25	50		
t <sub>jphPCle6-CC</sub>		PCle Gen 6 (64 GT/s) [3][6]	15	29		
t <sub>jphPCleG2-SRIS</sub>	Additive PCIe Refclk Jitter	PCle Gen 2 (5 GT/s)	139	301	N/A [7][8]	
t <sub>jphPCleG3-SRIS</sub>	in Fan-out Buffer Mode (SRIS Architecture, SSC =	PCle Gen 3 (8 GT/s)	36	80		fs RMS
t <sub>jphPCleG4-SRIS</sub>	0.0% or -0.5%)	PCle Gen 4 (16 GT/s)	38	83		
t <sub>jphPCleG5-SRIS</sub>	Additive PCIe Refclk Jitter	PCle Gen 5 (32 GT/s)	31	81	N/A [/][O]	IS KIVIS
t <sub>jphPCleG6-SRIS</sub>	in Fan-out Buffer Mode (SRIS Architecture, SSC = 0.0% or -0.3%)	PCIe Gen 6 (64 GT/s)	40	97		
t <sub>jphPCleG2-SRNS</sub>		PCle Gen 2 (5 GT/s)	148	286		
t <sub>jphPCleG3-SRNS</sub>	Additive PCIe Refclk Jitter	PCle Gen 3 (8 GT/s)	39	77		
t <sub>jphPCleG4-SRNS</sub>	in Fan-out Buffer Mode (SRNS Architecture, SSC =	PCle Gen 4 (16 GT/s)	40	79	N/A [7][8]	fs RMS
t <sub>jphPCleG5-SRNS</sub>	0%)	PCle Gen 5 (32 GT/s)	34	83		
t <sub>jphPCleG6-SRNS</sub>		PCle Gen 6 (64 GT/s)	44	95		

- 1. The Refclk jitter is measured after applying the filter functions found in *PCI Express Base Specification 6.0, Revision 0.9*. See the "Test Loads" section of the datasheet for the exact measurement setup. The worst case results for each data rate are summarized in this table. Equipment noise is removed from all measurements.
- 2. Jitter measurements should be made with a capture of at least 100,000 clock cycles captured by a real-time oscilloscope (RTO) with a sample rate of 20GS/s or greater. Broadband oscilloscope noise must be minimized in the measurement. The measured PP jitter is used (no extrapolation) for RTO measurements. Alternately, jitter measurements can be used with a Phase Noise Analyzer (PNA) extending (flat) and integrating and folding the frequency content up to an offset from the carrier frequency of at least 200MHz (at 300MHz absolute frequency) below the Nyquist frequency. For PNA measurements for the 2.5GT/s data rate, the RMS jitter is converted to peak-to-peak jitter using a multiplication factor of 8.83.
- 3. SSC spurs from the fundamental and harmonics are removed up to a cutoff frequency of 2MHz taking care to minimize removal of any non-SSC content.
- 4. Note that 0.7ps RMS is to be used in channel simulations to account for additional noise in a real system.
- 5. Note that 0.25ps RMS is to be used in channel simulations to account for additional noise in a real system.
- 6. Note that 0.15ps RMS is to be used in channel simulations to account for additional noise in a real system.
- 7. The PCI Express Base Specification 6.0, Revision 0.9 provides the filters necessary to calculate SRIS and SRNS jitter values; it does not provide specification limits, hence the N/A in the Limit column. SRIS and SRNS values are informative only. A common practice is to split the common clock budget in half. For 16GT/s data rates and above, the user must choose whether to use the output jitter specification, or the input jitter specification, which includes an allocation for the jitter added by the channel. Using 32GT/s, the Refclk jitter budget is 150fs RMS. One half of the Refclk jitter budget is 106fs RMS. At the clock input, the system must deliver 250fs RMS. One half of this value is 177fs RMS. If the clock is placed next to the PCIe device in an SRIS system, the channel is very short and the user may choose to use this more relaxed value as the jitter limit.
- 8. The RMS sum of the source jitter and the additive jitter must be less than the jitter specification listed for the clock generator operating mode.

Table 12. Phase Jitter and Phase Noise - 1.8V VDDO [1][2]

Symbol	Parameter	Conditions	Typical	Maximum	Unit
	Random Phase Jitter, 10kHz to 20MHz (78.125MHz XTAL, Synthesizer Mode) <sup>[2]</sup>	122.88MHz (VCO: 9.8304GHz, FOD 0, 1 or 2)	166	212	
		156.25MHz (VCO: 10GHz, FOD 0, 1 or 2)	160	265	
tjit(Φ)		245.76MHz (VCO: 9.8304GHz, FOD 0, 1 or 2)	190	261	fs
$\mathfrak{gll}(\Psi)$		312.5MHz (VCO: 10GHz, FOD 0, 1 or 2)	137	227	(RMS)
		322.265625MHz (VCO: 10.3125GHz, FOD 0, 1 or 2)	138	173	
		644.53125MHz (VCO: 10.3125GHz, FOD 0, 1 or 2)	125	155	

Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is
mounted in a test socket with maintained transverse airflow greater than 500lfpm. The device will meet specifications after thermal
equilibrium has been reached under these conditions.

Table 13. Phase Jitter and Phase Noise – 2.5V VDDO [1][2]

Symbol	Parameter	Conditions	Typical	Maximum	Unit
	Random Phase Jitter,	122.88MHz (VCO: 9.8304GHz, FOD 0, 1 or 2)	178	227	
		156.25MHz (VCO: 10GHz, FOD 0, 1 or 2)	169	247	
tjit(Φ)	10kHz to 20MHz	245.76MHz (VCO: 9.8304GHz, FOD 0, 1 or 2)	209	228	fs
igit(Ψ)	(78.125MHz XTAL, Synthesizer Mode) [2]	312.5MHz (VCO: 10GHz, FOD 0, 1 or 2)	149		(RMS)
	Syntholizar Midday :	322.265625MHz (VCO: 10.3125GHz, FOD 0, 1 or 2)	156	278	
		644.53125MHz (VCO: 10.3125GHz, FOD 0, 1 or 2)	155	250	

<sup>1.</sup> Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500lfpm. The device will meet specifications after thermal equilibrium has been reached under these conditions.

Table 14. Phase Jitter and Phase Noise – 3.3V VDDO [1][2]

Symbol	Parameter	Conditions	Typical	Maximum	Unit
	Random Phase Jitter, 10kHz to 20MHz (78.125MHz XTAL, Synthesizer Mode) <sup>[2]</sup>	122.88MHz (VCO: 9.8304GHz, FOD 0, 1 or 2)	168	218	
		156.25MHz (VCO: 10GHz, FOD 0, 1 or 2)	164	226	
tiit(क)		245.76MHz (VCO: 9.8304GHz, FOD 0, 1 or 2)	206	234	fs
ijit(Ψ)		312.5MHz (VCO: 10GHz, FOD 0, 1 or 2)	145	192	(RMS)
		322.265625MHz (VCO: 10.3125GHz, FOD 0, 1 or 2)	154	188	
		644.53125MHz (VCO: 10.3125GHz, FOD 0, 1 or 2)	141	162	

<sup>1.</sup> Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500lfpm. The device will meet specifications after thermal equilibrium has been reached under these conditions.

<sup>2.</sup> Characterized using a Rohde and Schwarz SMA100 overdriving the XTAL interface.

<sup>2.</sup> Characterized using a Rohde and Schwarz SMA100 overdriving the XTAL interface.

<sup>2.</sup> Characterized using a Rohde and Schwarz SMA100 overdriving the XTAL interface.

Table 15. Clock Input Frequencies [1]

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Unit
	Over-driving Crystal Input, Doubler Logic Disabled	1	-	650		
f <sub>INAPLL</sub>	APLL Input Frequency for clock generation.	Over-driving Crystal Input, Doubler Logic Enabled	1	-	250	MHz
		CLKIN[1:0] Differential Mode	1	-	650	
		CLKIN[1:0] Single-ended Mode	1	-	250	

<sup>1.</sup> For crystal characteristics, see Table 16.

**Table 16. External Crystal Characteristics** 

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Unit
-	Resonance Mode	-		Fundamental		-
f <sub>INXTAL</sub> [1]	Crystal input frequency	Fundamental mode	8	-	80	MHz
		$8MHz \le f_{INXTAL} \le 12MHz, C_L = 12pF$	-	-	120	
EQD [1]	ESR [1] Equivalent Series Resistance	12MHz < f <sub>INXTAL</sub> ≤ 28MHz, C <sub>L</sub> = 12pF	-	-	80	Ω
ESINT		28MHz < f <sub>INXTAL</sub> ≤ 54MHz, C <sub>L</sub> = 12pF	-	-	50	(2
		54MHz < f <sub>INXTAL</sub> ≤ 80MHz, C <sub>L</sub> = 8pF	-	-	50	
C <sub>O</sub> [1]	Shunt Capacitance		-	7	-	n.E
C <sub>L</sub> [1]	Load Capacitance		6	8	12	pF
Drive [1]	Drive Level		-	-	100	μW
F <sub>TOL</sub>	Frequency Tolerance	Center frequency at 25°C	-	-		
F <sub>STAB</sub>	Frequency Stability	Over Operating Temperature Range with respect to F <sub>TOL</sub>	-	-	[2]	ppm
Aging	Per Year		-	-		

<sup>1.</sup> These parameters are required, regardless of crystal used.

Table 17. Internal Crystal Characteristics (Q Versions Only)

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Unit
-	Resonance Mode			Fundamental		-
f <sub>INXTAL</sub>	Crystal frequency	Fundamental mode	-	78.125	-	MHz
F <sub>STAB</sub>	Frequency Stability	Includes both initial accuracy and variation over temperature.	-	-	±30	ppm
-	Aging	Over the first ten years	-	-	±5	

Table 18. Output Frequencies and Startup Times [1]

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Unit
f <sub>OUT</sub> Output Frequency	Differential Output.	0.001	-	650	MHz	
TOUT	Output Frequency	LVCMOS Output.	0.001	-	200	IVII IZ



<sup>2.</sup> These parameters are customer/application dependent. Common maximum values are F<sub>TOL</sub> = ±20ppm, F<sub>STAB</sub> = ±20ppm, and Aging = ±5ppm/10years. The customer is free to adjust these parameters to their particular requirements.

Table 18. Output Frequencies and Startup Times [1] (Cont.)

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Unit
f <sub>MON</sub>	Reference Monitor Operating Frequency		-	-	40	MHz
$f_{VCO}$	VCO (APLL) Operating Frequency		9.5	-	10.7	GHz
t <sub>STARTUP</sub>	Start-up Time [2][3]	Synthesizer mode	-	6	10	ms

- 1. Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500lfpm. The device will meet specifications after thermal equilibrium has been reached under these conditions.
- 2. Measured from when all power supplies have reached > 90% of nominal voltage to the first stable clock edge on the output. A stable clock is defined as one generated from a locked PLL (as appropriate for the configuration listed) with no further perturbations in frequency expected. Includes time needed to load a configuration from internal OTP. For important additional power supply sequencing considerations, see Power Considerations.
- 3. Start-up time will depend on the actual configuration used. For more information, please contact Renesas technical support

Table 19. Output-to-Output, Input-to-Output Skew - LP-HCSL Outputs 1.8V/2.5V/3.3V VDDO [1]

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Unit
t <sub>SK</sub> Output-to-C		FOD1 driving output banks [2:4]	-	18	90	
	Output to Output Clean [2][3]	FOD1 driving all output banks	-	39	124	
	Output-to-Output Skew [2][3]	FOD1 driving Bank2	-	21	63	ps
		IOD1 driving bank 2	-	22	65	-
t <sub>PD</sub>	Input-to-Output Delay [3][4]	Fanout buffer path to any output	1.2	2	2.6	ns
$\Delta t_{PD}$	Input-to-Output Delay Variation [3][4]	Fanout buffer, single device, at a fixed voltage, over temperature	-	2	4	ps/°C

- 1. Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500lfpm. The device will meet specifications after thermal equilibrium has been reached under these conditions.
- 2. Defined as the time between the rising edges of two outputs of the same frequency, configuration, loading, and supply voltage.
- 3. This parameter is defined in accordance with JEDEC Standard 65
- 4. Defined as the time between to output rising edge and the input rising edge that caused it.

Table 20. Output-to-Output, Input-to-Output Skew - LVDS Outputs 1.8V/2.5V/3.3V VDDO [1]

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Unit
		FOD1 driving output banks [2:4]	-	16	93	
<b>t</b>	Output-to-Output Skew [2][3]	FOD1 driving all output banks	-	44	101	ne
<sup>1</sup> SK	t <sub>SK</sub> Output-to-Output Skew <sup>[2][3]</sup>	FOD1 driving Bank2	-	14	53	- ps
		IOD1 driving bank 2	-	20	67	
t <sub>PD</sub>	Input-to-Output Delay [3][4]	Fanout buffer path to any output	1.3	2	2.8	ns

- 1. Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500lfpm. The device will meet specifications after thermal equilibrium has been reached under these conditions.
- 2. Defined as the time between the rising edges of two outputs of the same frequency, configuration, loading, and supply voltage.
- 3. This parameter is defined in accordance with JEDEC Standard 65
- 4. Defined as the time between to output rising edge and the input rising edge that caused it.



Table 21. Output-to-Output, Input-to-Output Skew – LVCMOS Outputs 1.8V/2.5V/3.3V VDDO [1]

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Unit
		FOD1 driving output banks [2:4]	-	50	130	
	Output to Output Skow [2][3]	FOD1 driving all output banks	-	76	180	
t <sub>SK</sub>	Output-to-Output Skew [2][3]	FOD1 driving Bank2	-	22	64	ps
		IOD1 driving bank 2	-	29	79	
t <sub>PD</sub> Input-to-Output Delay		Fanout buffer path to any output - 1.8V VDDO	2.3	3.2	4.3	
	Input-to-Output Delay [3][4]	Fanout buffer path to any output - 2.5V VDDO	1.7	2.4	3.4	ns
		Fanout buffer path to any output - 3.3V VDDO	1.6	2.2	3	

<sup>1.</sup> Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500lfpm. The device will meet specifications after thermal equilibrium has been reached under these conditions.

- 2. Defined as the time between the rising edges of two outputs of the same frequency, configuration, loading, and supply voltage.
- 3. This parameter is defined in accordance with JEDEC Standard 65
- 4. Defined as the time between to output rising edge and the input rising edge that caused it.

Table 22. Static Phase Offset - Zero Delay Buffer Mode

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Unit
+	APLL Static Phase	LVDS or LP-HCSL signaling, feedback frequency = 50MHz. VDDR = VDDOx = 2.5V or 3.3V. CLKIN0 used as feedback in.	-	197	270	ne
ФАРЦ	t <sub>ФAPLL</sub> APLL Static Phase Offset [1]	LVDS or LP-HCSL signaling, feedback frequency = 50MHz. VDDR = VDDOx = 1.8V. CLKIN0 used as feedback in.	-	192	350	ps

<sup>1.</sup> This parameter is defined in accordance with JEDEC Standard 65B, which defines static phase offset as the time interval between similar points on the waveforms of the averaged input reference clock and the averaged feedback input signal when the PLL is locked and the input reference frequency is stable.

Table 23. LVCMOS AC/DC Output Characteristics – 1.8V VDDO<sup>[1]</sup>

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Unit
V <sub>OH</sub>	Output High Voltage [2]	I <sub>OH</sub> = -2mA	1.6	1.75	VDDO + 0.3	V
V <sub>OL</sub>	Output Low Voltage [2]	I <sub>OL</sub> = 2mA	-	0.04	0.4	
I <sub>OZ</sub>	Output Leakage Current	Outputs Tri-stated	-5	-	5	μΑ
		ODRV_CNFG[3:2] = 0	0.8	1.5	2.2	
dV/dt	Slew Rate <sup>[3]</sup>	ODRV_CNFG[3:2] = 1	0.7	1.5	2.2	V/ns
d v/dt	Olew Itale: 1	ODRV_CNFG[3:2] = 2	0.7	1.5	2.4	- V/IIS
		ODRV_CNFG[3:2] = 3	0.8	1.5	2.3	
tDC	Output Duty Cycle	V <sub>T</sub> = VDDO/2	45	51	55	%

- 1. See Test Loads for additional information.
- 2. These values are compliant with JESD8-7A.
- 3.  $V_T = 20\%$  to 80% of VDDO,  $C_L = 4.7$ pF.

Table 24. LVCMOS AC/DC Output Characteristics – 2.5V VDDO<sup>[1]</sup>

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Unit
V <sub>OH</sub>	Output High Voltage [2]	I <sub>OH</sub> = -2mA	2.2	2.4	VDDO + 0.3	٧
V <sub>OL</sub>	Output Low Voltage [2]	I <sub>OL</sub> = 2mA	-	0.04	0.4	
I <sub>OZ</sub>	Output Leakage Current	Outputs Tri-stated	-5	-	5	μА
		ODRV_CNFG[3:2] = 0	1.2	2.2	3.6	
dV/dt	Slew Rate[3]	ODRV_CNFG[3:2] = 1	0,6	1.6	3.2	V/ns
u v/ut	Siew (Valer-)	ODRV_CNFG[3:2] = 2	0,5	1.4	2.6	V/115
		ODRV_CNFG[3:2] = 3	0.9	2.0	3.4	
tDC	Output Duty Cycle	V <sub>T</sub> = VDDO/2	45	51	55	%

- 1. See Test Loads for additional information.
- 2. These values are compliant with JESD8-5A.01.
- 3.  $V_T = 20\%$  to 80% of VDDO,  $C_L = 4.7 pF$ .

Table 25. LVCMOS AC/DC Output Characteristics – 3.3V VDDO<sup>[1]</sup>

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Unit
V <sub>OH</sub>	Output High Voltage [2]	I <sub>OH</sub> = -2mA	2.4	3.2	VDDO + 0.3	V
V <sub>OL</sub>	Output Low Voltage [2]	I <sub>OL</sub> = 2mA	-	0.03	.03 0.4	
I <sub>OZ</sub>	Output Leakage Current	Outputs Tri-stated	-5	-	5	μА
		ODRV_CNFG[3:2] = 0	1.3	3.1	4.9	
dV/dt	Slew Rate <sup>[3]</sup>	ODRV_CNFG[3:2] = 1	1.2	2.5	4.0	V/ns
d v/dt	Olew Itale: 1	ODRV_CNFG[3:2] = 2	1.2	2.4	4.0	- V/IIS
		ODRV_CNFG[3:2] = 3	1.4	2.8	4.1	
tDC	Output Duty Cycle	V <sub>T</sub> = VDDO/2	45	50.7	55	%

- 1. See Test Loads for additional information.
- 2. These values are compliant with JESD8C.01.
- 3.  $V_T = 20\%$  to 80% of VDDO,  $C_L = 4.7 pF$ .

Table 26. LVDS AC/DC Output Characteristics – 1.8V  $V_{DDO}$  [1]

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Unit
V <sub>OT</sub> (+)	TRUE binary state.	out prog = 0x00	243	346	448	mV
V <sub>OT</sub> (-)	FALSE binary state.	out_prog oxou	-462	-355	-248	111 V
V <sub>OT</sub> (+)	TRUE binary state.	out_prog = 0x01	257	362	468	mV
V <sub>OT</sub> (-)	FALSE binary state.		-482	-372	-262	111 V
V <sub>OT</sub> (+)	TRUE binary state.	out prog = 0x02	219	310	400	mV
V <sub>OT</sub> (-)	FALSE binary state.	out_prog = 0x02	-419	-323	-227	IIIV
V <sub>OT</sub> (+)	TRUE binary state.	out prog = 0x03	232	328	425	mV
V <sub>OT</sub> (-)	FALSE binary state.	out_prog = 0x00	-441	-338	-235	111 V

Table 26. LVDS AC/DC Output Characteristics – 1.8V  $V_{DDO}$  [1] (Cont.)

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Unit
ΔV <sub>OT</sub>	Change in V <sub>OT</sub> between Complimentary Output States		14	37	60	mV
V <sub>CMR</sub>	Output Common Mode Voltage		1.07	1.21	1.35	V
ΔV <sub>CMR</sub>	Change in V <sub>CMR</sub> between Complimentary Output States		-	25	37	mV
I <sub>OS</sub>	Output Short Circuit Current	V <sub>OUT+</sub> or V <sub>OUT-</sub> = 0V or VDD	-	7.5	-	
I <sub>OSD</sub>	Differential Output Short Circuit Current	V <sub>OUT+</sub> = V <sub>OUT-</sub>	-	3.3	-	mA
t <sub>R</sub> /t <sub>F</sub>	Rise/Fall Time <sup>[2]</sup> V <sub>T</sub> = 20% to 80% of swing.		138	252	365	ps
t <sub>DC</sub>	Output Duty Cycle	V <sub>T</sub> = 0V differential	43.9	49.7	54.3	%

<sup>1.</sup> See Test Loads for additional test conditions.

Table 27. LVDS AC/DC Output Characteristics – 2.5V/3.3V  $V_{DDO}$  [1]

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Unit
V <sub>OT</sub> (+)	TRUE binary state.	out_prog = 0x00	240	348	457	mV
V <sub>OT</sub> (-)	FALSE binary state.	out_prog = 0x00	-464	-356	-247	IIIV
V <sub>OT</sub> (+)	TRUE binary state.	out prog = 0x01	255	366	477	- mV
V <sub>OT</sub> (-)	FALSE binary state.	out_prog = 0x01	-483	-372	-261	IIIV
V <sub>OT</sub> (+)	TRUE binary state.	out prog = 0x02	211	311	411	mV
V <sub>OT</sub> (-)	FALSE binary state.	- out_prog = 0x02	-427	-325	-224	IIIV
V <sub>OT</sub> (+)	TRUE binary state.	out prog = 0x03	225	330	434	mV
V <sub>OT</sub> (-)	FALSE binary state.	- out_prog = 0x03	-446	-341	-235	IIIV
ΔV <sub>OT</sub>	Change in V <sub>OT</sub> between Complimentary Output States		14	37	60	mV
V <sub>CMR</sub>	Output Common Mode Voltage		1.16	1.21	1.32	V
ΔV <sub>CMR</sub>	Change in V <sub>CMR</sub> between Complimentary Output States		-	25	37	mV
Ios	Output Short Circuit Current	V <sub>OUT+</sub> or V <sub>OUT-</sub> = 0V or VDD	-	7.5	-	
I <sub>OSD</sub>	Differential Output Short Circuit Current	V <sub>OUT+</sub> = V <sub>OUT-</sub>	-	3.3	-	mA
t <sub>R</sub> /t <sub>F</sub>	Rise/Fall Time $[2]$ V <sub>T</sub> = 20% to 80% of swing.		138	252	365	ps
t <sub>DC</sub>	Output Duty Cycle	V <sub>T</sub> = 0V differential	43.9	49.7	54.3	%

<sup>1.</sup> See Test Loads for additional test conditions.

<sup>2.</sup> Single-ended measurement

<sup>2.</sup> Single-ended measurement

Table 28. LP-HCSL AC/DC Characteristics, Non-PCle Frequencies – 1.8V  $V_{\rm DDO}^{\,\,[1]}$ 

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Unit
V	Output High Voltage <sup>[2]</sup> f < 400MHz		680	849	1018	
V <sub>OH</sub>	Output High Voltage <sup>[2]</sup> f ≥ 400MHz		522	657	792	mV
V <sub>OL</sub>	Output Low Voltage [2]		-130	-4	123	
V <sub>CROSS</sub>	Crossing Voltage (abs) [3]	V <sub>HIGH</sub> = 800mV,	166	423	680	
ΔV <sub>CROSS</sub>	Crossing Voltage (var) [3][4][5]	<ul><li>Fast Slew Rate, 25MHz, 100MHz, 156.25MHz, 312.5MHz or</li></ul>	-	30	43	
. //	Rise/Fall Time $[2]$ V <sub>T</sub> = 20% to 80% of swing, f < 400MHz	625MHz.	232	392	552	ps
t <sub>R</sub> /t <sub>F</sub>	Rise/Fall Time <sup>[2]</sup> $V_T = 20\%$ to 80% of swing, $f \ge 400MHz$		160	300	439	
.,	Output High Voltage <sup>[2]</sup> f < 400MHz		718	924	1130	
V <sub>OH</sub>	Output High Voltage <sup>[2]</sup> f ≥ 400MHz		551	703	855	mV
V <sub>OL</sub>	Output Low Voltage [2]		-164	-2	160	
V <sub>CROSS</sub>	Crossing Voltage (abs) [3]	V <sub>HIGH</sub> = 900mV,	170	446	722	
ΔV <sub>CROSS</sub>	Crossing Voltage (var) [3][4][5]	<ul><li>Fast Slew Rate, 25MHz, 100MHz, 156.25MHz, 312.5MHz or</li></ul>	-	27	41	
. //	Rise/Fall Time <sup>[2]</sup> V <sub>T</sub> = 20% to 80% of swing, f < 400MHz	625MHz.	217	402	588	
t <sub>R</sub> /t <sub>F</sub>	Rise/Fall Time [2] $V_T = 20\% \text{ to } 80\% \text{ of swing,}$ $f \ge 400\text{MHz}$		169	298	428	ps
t	Output Duty Cycle [6]	Across all settings, $f < 400MHz$ $V_T = 0V$ .	47	50	53	- %
t <sub>DC</sub>	Cutput Duty Cycle (-)	Across all settings, f ≥ 400MHz V <sub>T</sub> = 0V.	45	50	55	70

- 1. Standard high impedance load with  $C_L$ = 2pF. See Test Loads
- 2. Measured from single-ended waveform.
- 3. Measured at crossing point where the instantaneous voltage value of the rising edge of CLK equals the falling edge of CLKb.
- 4. Refers to the total variation from the lowest crossing point to the highest, regardless of which edge is crossing. Refers to all crossing points for this measurement.
- 5. Defined as the total variation of all crossing voltages of Rising CLK and Falling CLKb. This is the maximum variance in V<sub>CROSS</sub> for any particular system.
- 6. Measured from differential waveform.

Table 29. LP-HCSL AC/DC Characteristics, Non-PCle Frequencies – 2.5V/3.3V  $V_{DDO}^{\ [1]}$ 

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Unit
V <sub>OH</sub>	Output High Voltage <sup>[2]</sup> f < 400MHz.		667	861	1055	mV
VOH	Output High Voltage <sup>[2]</sup> f ≥ 400MHz.		552	717	881	mV
V <sub>OL</sub>	Output Low Voltage [2]		-164	-4	156	mV
V <sub>CROSS</sub>	Crossing Voltage (abs) [3]	V <sub>HIGH</sub> = 800mV,	261	384	507	mV
ΔV <sub>CROSS</sub>	Crossing Voltage (var) [3][4][5]	- Fast Slew Rate, 25MHz, 100MHz, 156.25MHz, 312.5MHz or	-	27	42	mV
4 /4	Rise/Fall Time <sup>[2]</sup> $V_T = 20\%$ to 80% of swing, f < 400MHz.	625MHz.	214	393	606	
t <sub>R</sub> /t <sub>F</sub>	Rise/Fall Time [2] $V_T = 20\% \text{ to } 80\% \text{ of swing}$ $f \ge 400\text{MHz}$		148	302	456	ps
V	Output High Voltage [2] f < 400MHz.	694	917	1140	mV	
V <sub>OH</sub>	Output High Voltage <sup>[2]</sup> f ≥ 400MHz.		598	757	917	mV
V <sub>OL</sub>	Output Low Voltage [2]		-164	-8	148	mV
V <sub>CROSS</sub>	Crossing Voltage (abs) [3]	V <sub>HIGH</sub> = 900mV, Fast Slew Rate, 25MHz, 100MHz,	238	455	673	mV
$\Delta V_{CROSS}$	Crossing Voltage (var) [3][4][5]	156.25MHz, 312.5MHz or	-	27	42	mV
+ /+	Rise/Fall Time [2] $V_T = 20\%$ to 80% of swing, $f < 400MHz$ .	625MHz.	218	397	581	
t <sub>R</sub> /t <sub>F</sub>	Rise/Fall Time [2] $V_T = 20\%$ to 80% of swing $f \ge 400MHz$		174	300	426	- ps
too	Output Duty Cycle [6]	Across all settings, f < 400MHz V <sub>T</sub> = 0V.	48	50	52	<u></u> %
t <sub>DC</sub>	Super Buty Gyde (1)	Across all settings, f ≥ 400MHz V <sub>T</sub> = 0V.	45	50	55	70

<sup>1.</sup> Standard high impedance load with  $C_L$ = 2pF. See Test Loads.

<sup>2.</sup> Measured from single-ended waveform.

<sup>3.</sup> Measured at crossing point where the instantaneous voltage value of the rising edge of CLK equals the falling edge of CLKb.

<sup>4.</sup> Refers to the total variation from the lowest crossing point to the highest, regardless of which edge is crossing. Refers to all crossing points for this measurement.

<sup>5.</sup> Defined as the total variation of all crossing voltages of Rising CLK and Falling CLKb. This is the maximum allowed variance in V<sub>CROSS</sub> for any particular system.

<sup>6.</sup> Measured from differential waveform.

Table 30. LP-HCSL AC/DC Characteristics, 100MHz PCIe – 1.8V  $V_{\rm DDO}$  [1]

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Spec. Limit [2]	Unit
V <sub>MAX</sub>	Absolute Max Voltage Includes 300mV of overshoot (Vovs) [3][4]	V	-	-	1103	1150	
V <sub>MIN</sub>	Absolute Min Voltage Includes -300mV of undershoot (Vuds) [3][5]	V <sub>HIGH</sub> set to 900mV.	-152	-	-	-300	mV
$V_{HIGH}$	Voltage High [3]	\/ act to 900m\/	825	886	984	-	
$V_{LOW}$	Voltage Low [3]	V <sub>HIGH</sub> set to 800mV.	-70	-15	44	-	m\/
V <sub>CROSS</sub>	Crossing Voltage (abs) [3][6][7]	V <sub>HIGH</sub> set to 800mV,	266	406	545	250 to 550	- mV
$\Delta V_{CROSS}$	Crossing Voltage (var) [3][6][8]	scope averaging off.	-	27	49	140	
als (/alt	Claurate [9][10]	V <sub>HIGH</sub> set to 800mV, Fast slew rate, scope averaging on.	1.6	2.6	3.6	1 to 4	Man
dv/dt	Slew rate <sup>[9][10]</sup>	V <sub>HIGH</sub> set to 800mV, Slow slew rate, scope averaging on.	1.2	1.8	2.4	1 to 4	V/ns
ΔT <sub>R/F</sub>	Rise/fall matching [3][11]	V <sub>HIGH</sub> set to 800mV. Fast or slow slew rate.	-	7	19.3	20	%
$V_{HIGH}$	Voltage High [3]	\/	844	940	1037	-	
$V_{LOW}$	Voltage Low [3]	V <sub>HIGH</sub> set to 900mV.	-79	-14	51	-	\/
V <sub>CROSS</sub>	Crossing Voltage (abs) [3][6][7]	V <sub>HIGH</sub> set to 900mV,	301	451	600	300 to 600	mV
$\Delta V_{CROSS}$	Crossing Voltage (var) [3][6][8]	scope averaging off.	-	28	44	140	-
-1/-14	Slew rate [9][10]	V <sub>HIGH</sub> set to 900mV, Fast slew rate, scope averaging on.	1.7	2.7	3.7	44-4	Mar
dv/dt	Siew rate (9)(19)	V <sub>HIGH</sub> set to 900mV, Slow slew rate, scope averaging on.	1.3	1.9	2.5	1 to 4	V/ns
ΔT <sub>R/F</sub>	Rise/fall matching [3][11]	V <sub>HIGH</sub> set to 900mV. Fast or slow slew rate.	-	4	18.5	20	%
t <sub>DC</sub>	Output Duty Cycle [9]	V <sub>T</sub> = 0V differential.	49	50	51	45 to 55	
t <sub>jcyc-cyc</sub>	Jitter, Cycle to cycle [9]	Across all settings in this table at 100MHz.	-	33	49.3	50	ps

- 1. Standard high impedance load with C<sub>I</sub> = 2pF. See Test Loads.
- 2. The specification limits are taken from either the *PCle Base Specification Revision 6.0* or from relevant x86 processor specifications, whichever is more stringent.
- 3. Measured from single-ended waveform.
- 4. Defined as the maximum instantaneous voltage including overshoot.
- 5. Defined as the minimum instantaneous voltage including undershoot.
- 6. Measured at crossing point where the instantaneous voltage value of the rising edge of REFCLK+ equals the falling edge of REFCLK-.
- 7. Refers to the total variation from the lowest crossing point to the highest, regardless of which edge is crossing. Refers to all crossing points for this measurement.
- 8. Defined as the total variation of all crossing voltages of Rising REFCLK+ and Falling REFCLK-. This is the maximum allowed variance in V<sub>CROSS</sub> for any particular system.



- 9. Measured from differential waveform.
- 10. Measured from -150 mV to +150 mV on the differential waveform (derived from REFCLK+ minus REFCLK-). The signal must be monotonic through the measurement region for rise and fall time. The 300 mV measurement window is centered on the differential zero crossing.
- 11. Matching applies to rising edge rate for REFCLK+ and falling edge rate for REFCLK-. It is measured using a ±75 mV window centered on the median cross point where REFCLK+ rising meets REFCLK- falling. The median cross point is used to calculate the voltage thresholds the oscilloscope is to use for the edge rate calculations. The Rise Edge Rate of REFCLK+ should be compared to the Fall Edge Rate of REFCLK-; the maximum allowed difference should not exceed 20% of the slowest edge rate.

Table 31. LP-HCSL AC/DC Characteristics, 100MHz PCIe – 2.5V/3.3V V<sub>DDO</sub> [1]

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Spec. Limit [2]	Unit
$V_{MAX}$	Absolute Max Voltage Includes 300mV of overshoot (Vovs) [3][4]		-	-	1088	1150	
$V_{MIN}$	Absolute Min Voltage Includes -300mV of undershoot (Vuds) [3][5]	V <sub>HIGH</sub> set to 900mV.	-174	-	-	-300	mV
$V_{HIGH}$	Voltage High [3]	\/ astts 000m\/	743	869	994	-	
$V_{LOW}$	Voltage Low [3]	V <sub>HIGH</sub> set to 800mV.	-92	-7	58	-	
V <sub>CROSS</sub>	Crossing Voltage (abs) [3][6][7]	V <sub>HIGH</sub> set to 800mV,	256	406	533	250 to 550	mV
$\Delta V_{CROSS}$	Crossing Voltage (var) [3][6][8]	scope averaging off.	-	27	40	140	
als (/al4	Slew rate [9][10]	V <sub>HIGH</sub> set to 800mV, Fast slew rate, scope averaging on.	1.3	2.6	3.9	1 to 1	V/ns
dv/dt	Siew rate loit of	V <sub>HIGH</sub> set to 800mV, Slow slew rate, scope averaging on.	1	1.7	3.1	1 to 4	V/IIS
$\Delta T_{R/F}$	Rise/fall matching [3][11]	V <sub>HIGH</sub> set to 800mV. Fast or slow slew rate.	-	8	19.7	20	%
$V_{HIGH}$	Voltage High [3]	\/++- 000\/	800	925	1051	-	
$V_{LOW}$	Voltage Low [3]	V <sub>HIGH</sub> set to 900mV.	-95	-2	68	-	\ /
V <sub>CROSS</sub>	Crossing Voltage (abs) [3][6][7]	V <sub>HIGH</sub> set to 900mV,	286	454	629	250 to 600	mV
$\Delta V_{CROSS}$	Crossing Voltage (var) [3][6][8]	scope averaging off.	-	27	40	140	
-l/-l4	Slew rate [9][10]	V <sub>HIGH</sub> set to 900mV, Fast slew rate, scope averaging on.	1.4	2.8	4.2	44-40	N//
dv/dt	Siew rate loit of	V <sub>HIGH</sub> set to 900mV, Slow slew rate, scope averaging on.	1.2	2.0	3	1 to 4.2	V/ns
$\Delta T_{R/F}$	Rise/fall matching [3][11]	V <sub>HIGH</sub> set to 900mV. Fast or slow slew rate.	-	6	18.7	20	%
t <sub>DC</sub>	Output Duty Cycle [9]	V <sub>T</sub> = 0V differential.	49	50	51	45 to 55	
t <sub>jcyc-cyc</sub>	Jitter, Cycle to cycle [9]	Across all settings in this table at 100MHz.	-	30	48.3	50	ps

<sup>1.</sup> Standard high impedance load with  $C_L$ = 2pF. See Test Loads.

<sup>2.</sup> The specification limits are taken from either the *PCle Base Specification Revision 6.0* or from relevant x86 processor specifications, whichever is more stringent.

<sup>3.</sup> Measured from single-ended waveform.

- 4. Defined as the maximum instantaneous voltage including overshoot.
- 5. Defined as the minimum instantaneous voltage including undershoot.
- 6. Measured at crossing point where the instantaneous voltage value of the rising edge of REFCLK+ equals the falling edge of REFCLK-.
- 7. Refers to the total variation from the lowest crossing point to the highest, regardless of which edge is crossing. Refers to all crossing points for this measurement.
- 8. Defined as the total variation of all crossing voltages of Rising REFCLK+ and Falling REFCLK-. This is the maximum allowed variance in V<sub>CROSS</sub> for any particular system.
- 9. Measured from differential waveform.
- 10. Measured from -150 mV to +150 mV on the differential waveform (derived from REFCLK+ minus REFCLK-). The signal must be monotonic through the measurement region for rise and fall time. The 300 mV measurement window is centered on the differential zero crossing.
- 11. Matching applies to rising edge rate for REFCLK+ and falling edge rate for REFCLK-. It is measured using a ±75 mV window centered on the median cross point where REFCLK+ rising meets REFCLK- falling. The median cross point is used to calculate the voltage thresholds the oscilloscope is to use for the edge rate calculations. The Rise Edge Rate of REFCLK+ should be compared to the Fall Edge Rate of REFCLK-; the maximum allowed difference should not exceed 20% of the slowest edge rate.

Table 32. 100MHz PCIe Output Clock Accuracy and SSC

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	PCIe Limit <sup>[1]</sup>	Unit
T <sub>PERIOD_AVG_</sub> 32G_64G_CC	Average Clock Period Accuracy for devices supporting 32GT/s or 64GT/s CC mode at any speed. [2][3]	SSC ≤ -0.5%, includes spread- spectrum modulation, if any.	0	-	2410	-100 to +2600	
T <sub>PERIOD_AVG_</sub> 32G_64G_SRIS	Average Clock Period Accuracy for devices supporting 32GT/s SRIS mode at any speed. [2][3]	SSC ≤ -0.3%, includes spread- spectrum modulation, if any.	0	-	1430	-100 to +1600	ppm
T <sub>PERIOD_AVG_</sub> 32G_64G	Average Clock Period Accuracy for devices supporting 32GT/s CC/SRNS mode at any speed. [2][3]	SSC = 0% (SSC Off).	0	-	0	±100	
T <sub>PERIOD_ABS_</sub> 32G_64G_CC	Average Clock Period Accuracy for devices supporting 32GT/s CC mode at any speed. [2][4]	SSC ≤ -0.5%, includes jitter and spread-spectrum modulation.	10	-	10.024	9.849 to 10.201	
T <sub>PERIOD_ABS_</sub> 32G_64G_SRIS	Average Clock Period Accuracy for devices supporting 32GT/s SRIS mode at any speed. [2][4]	SSC ≤ -0.3%, includes jitter and spread-spectrum modulation.	10	-	10.014	9.849 to 10.181	ns
T <sub>PERIOD_ABS_</sub> 32G_64G	Average Clock Period Accuracy for devices supporting 32GT/ s CC/SRNS mode at any speed. [2][4]	SSC = 0% (SSC Off), includes jitter.	10	-	10	9.849 to 10.151	
F <sub>REFCLK_32G_</sub> 64G	Refclk Frequency for devices that support 32GT/s or 64GT/s.	SSC = 0% (SSC Off)	100	-	100	99.99 to 100.01	MHz
F <sub>SSC</sub>	SSC Modulation Frequency		31.2	31.5	31.9	30 to 33	kHz
T <sub>SSC_FREQ_</sub> DEV	SSC Deviation for all devices and architectures except 32GT/s or 64GT/s devices operating in SRIS mode.	SSC = -0.5%	-0.490	-0.488	-0.486	-0.5	%

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	PCIe Limit <sup>[1]</sup>	Unit
T <sub>SSC_FREQ_</sub> DEV_32G_64G_ SRIS	SSC Deviation for devices that support 32 or 64GT/s operating in SRIS mode, at any speeds.	SSC = -0.3%	-0.300	-0.295	-0.290	-0.3	%
T <sub>SSC_MAX_</sub> FREQ_SLEW	Max df/dt of the SSC. [5]		-	310	372	1250	ppm/ us
T <sub>TRANSPORT</sub> _ DELAY	Tx-Rx transport delay used for PCIe Jitter calculations. <sup>[6]</sup>	Applies to Common Clocked architectures only.	-	-	12	12	ns

- 1. The specification limits are taken from either the PCIe Base Specification Revision 6.0 or from relevant x86 processor specifications, whichever is more stringent.
- 2. Measured from differential waveform.
- 3. PPM refers to parts per million and is a DC absolute period accuracy specification. 1 PPM is 1/1,000,000th of 100.000000MHz exactly or 100Hz. For 100PPM, then we have an error budget of 100Hz/PPM \* 100PPM = 10kHz. The period is to be measured with a frequency counter with measurement window set to 100 ms or greater. The ±100PPM applies to systems that do not employ Spread-Spectrum Clocking, or that use common clock source. For systems employing Spread-Spectrum Clocking, there is an additional 2,500PPM nominal shift in maximum period resulting from the 0.5% down spread resulting in a maximum average period specification of +2,600PPM for Common Clock Architectures. SRIS Architectures may have a lower allowed spread percentage. Devices meeting these specifications automatically meet the less stringent -300ppm to +2800ppm tolerances for data rates ≤16GT/s. Refer to Section 8.6 of the PCI Express Base Specification, Revision 6.0.
- 4. Defined as the absolute minimum or maximum instantaneous period. This includes cycle-to-cycle jitter, relative PPM tolerance, and spread-spectrum modulation. Devices meeting these specifications automatically meet the less stringent and 9.847ns to 10.203ns tolerances for data rates ≤16GT/s.
- 5. Measurement is made over a 0.5us time interval with a 1st order LPF with an fC of 60x the SSC modulation frequency (1.89MHz for 31.5kHz modulation frequency).
- 6. This is the default value used for all PCIe Common Clock architecture jitter calculations. There are form factors (for example topologies including long cables) that may exceed this limit. Contact Renesas for assistance calculating jitter if your topology exceeds 12ns.

**Table 33. Spread-Spectrum Programmability** 

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Unit
f <sub>SSCMOD</sub>	SSC Modulation Frequency	Modulation frequency.	30	-	63	kHz
SSC%	Spread percentage [1]	Down Spread.	-1	-	-0.05	%
330 //		Center Spread.	±0.025	-	±0.75	70
f <sub>outssc</sub>	Output frequency	Allowable output frequency range when SSC is enabled.	33	-	650	MHz

1. Spread off is 0%.

Table 34. GPI/GPIO Electrical Characteristics – 1.8V VDDD, VDDR, or VDDX [1][2]

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Unit
V <sub>IH</sub>	Input High Voltage [3]	XIN_REFIN, XOUT_REFINB, GPI[3:0], GPIO[4:0].	0.65 VDD	-	VDD + 0.3	
V <sub>IL</sub>	Input Low Voltage [3]	XIN_REFIN, XOUT_REFINB, GPI[3:0], GPIO[4:0].	-0.3	-	0.35 VDD	
V <sub>OH</sub>	Output High Voltage [3]	GPIO[4:0], IOH = -2mA.	VDD - 0.45	-	VDD + 0.3	V
V <sub>OL</sub>	Output Low Voltage [3]	GPIO[4:0], IOL = 2mA.	-	-	0.45	-
$V_{IH}$	Input High Voltage	GPIO[2:0], when set to tri-level.	0.75 VDD	-	VDD + 0.3	
$V_{IM}$	Input Mid Voltage	GPIO[2:0], when set to tri-level.	0.45 VDD	-	0.55 VDD	
V <sub>IL</sub>	Input Low Voltage	GPIO[2:0], when set to tri-level.	-0.3	-	0.25 VDD	

Input specifications refer to signals XIN\_REFIN, XOUT\_REFINb, GPI[3:0], GPIO[4:0], when acting as inputs. Output specifications refer
to signals GPIO[4:0], when acting as outputs. To determine which VDD pin is referenced for each group in Table 34, see GPI and GPIO
VDD pin assignments in Pin Information. For SCL\_SCLK, SDA\_SDI, see the I2C/SMBus electrical characteristics Table 39 and Table 40.

- 2. CLKIN[1:0]/CLKIN[1:0]b used as two single-ended clocks rather than as a differential clock.
- 3. These values are compliant with JESD8-7A. These values only apply to XIN\_REFIN and XOUT\_REFINB when "Input Buffer" mode is selected. See the Applications section for more details.

Table 35. GPI/GPIO Electrical Characteristics – 2.5V VDDD, VDDR, or VDDX [1][2]

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Unit
V <sub>IH</sub>	Input High Voltage <sup>[3]</sup>	XIN_REFIN, XOUT_REFINB, GPI[3:0], GPIO[4:0].	1.7	-	VDD + 0.3	
V <sub>IL</sub>	Input Low Voltage <sup>[3]</sup>	XIN_REFIN, XOUT_REFINB, GPI[3:0], GPIO[4:0].	-0.3	-	0.7	
V <sub>OH</sub>	Output High Voltage [3]	GPIO[4:0], IOH = -2mA.	1.7	-	VDD + 0.3	V
V <sub>OL</sub>	Output Low Voltage [3]	GPIO[4:0], IOL = 2mA.	-	-	0.7	
V <sub>IH</sub>	Input High Voltage	GPIO[2:0], when set to tri-level.	0.75 VDD	-	VDD + 0.3	
V <sub>IM</sub>	Input Mid Voltage	GPIO[2:0], when set to tri-level.	0.45 VDD	-	0.55 VDD	
V <sub>IL</sub>	Input Low Voltage	GPIO[2:0], when set to tri-level.	-0.3	-	0.25 VDD	

<sup>1.</sup> Input specifications refer to signals XIN\_REFIN, XOUT\_REFINb, GPI[3:0], GPI0[4:0], when acting as inputs. Output specifications refer to signals GPI0[4:0], when acting as outputs. To determine which VDD pin is referenced for each group in Table 35, see GPI and GPI0 VDD pin assignments in Pin Information. For SCL\_SCLK, SDA\_SDI, see the I2C/SMBus electrical characteristics Table 39 and Table 40.

- 2. CLKIN[1:0]/CLKIN[1:0]b used as two single-ended clocks rather than as a differential clock.
- 3. These values are compliant with JESD8-5A.01. These values only apply to XIN\_REFIN and XOUT\_REFINB when "Input Buffer" mode is selected. See the Applications section for more details.

Table 36. GPI/GPIO Electrical Characteristics – 3.3V VDDD, VDDR, or VDDX [1][2]

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Unit
V <sub>IH</sub>	Input High Voltage [3]	XIN_REFIN, XOUT_REFINB, GPI[3:0], GPIO[4:0].	2.2	-	VDD + 0.3	
V <sub>IL</sub>	Input Low Voltage [3]	XIN_REFIN, XOUT_REFINB, GPI[3:0], GPIO[4:0].	-0.3	-	0.8	
V <sub>OH</sub>	Output High Voltage [3]	GPIO[4:0], IOH = -2mA.	2.4	-	VDD + 0.3	V
V <sub>OL</sub>	Output Low Voltage [3]	GPIO[4:0], IOL = 2mA.	-	-	0.4	
$V_{IH}$	Input High Voltage	GPIO[2:0], when set to tri-level.	0.75 VDD	-	VDD + 0.3	
$V_{IM}$	Input Mid Voltage	GPIO[2:0], when set to tri-level.	0.45 VDD	-	0.55 VDD	
$V_{IL}$	Input Low Voltage	GPIO[2:0], when set to tri-level.	-0.3	-	0.25 VDD	

Input specifications refer to signals XIN\_REFIN, XOUT\_REFINb, GPI[3:0], GPIO[4:0], when acting as inputs. Output specifications refer
to signals GPIO[4:0], when acting as outputs. To determine which VDD pin is referenced for each group in Table 36, see GPI and GPIO
VDD pin assignments in Pin Information. For SCL\_SCLK, SDA\_SDI, see the I2C/SMBus electrical characteristics Table 39 and Table 40.

- 2. CLKIN[1:0]/CLKIN[1:0]b used as two single-ended clocks rather than as a differential clock.
- 3. These values are compliant with JESD8-5A.01. These values only apply to XIN\_REFIN and XOUT\_REFINB when "Input Buffer" mode is selected. See the Applications section for more details.

Table 37. CMOS GPI/GPIO Common Electrical Characteristics [1][2]

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Unit
I <sub>IL</sub>	Input Leakage Current	Includes input pull up/pull down resistor current. $V_{IL}$ = 0V, $V_{IH}$ = $V_{DD}$ .	-15	-	15	μА

<sup>1.</sup> Input specifications refer to signals XIN\_REFIN, XOUT\_REFINb, GPI[3:0], GPIO[4:0], when acting as inputs. Output specifications refer to signals GPIO[4:0], when acting as outputs. For VDD pin mapping, see GPI and GPIO VDD pin assignments in Pin Information.

Table 38. Power Supply Current [1]

Symbol	Parameter	Conditions	Typical	Maximum	Unit
		CMOS inputs (per input) [2][3]	11	20	
		HCSL inputs (per input pair) [3]	12	15	
		LVDS inputs (per input pair) [2][3]	13	14	
	V Supply Current	LVPECL inputs (per input pair) [3][4]  V <sub>DDR</sub> = 2.5V or 3.3V,	13	15	^
I <sub>DDR</sub>	V <sub>DDR</sub> Supply Current	CML inputs (per input pair) [3][4]  V <sub>DDR</sub> = 2.5V or 3.3V, input termination disabled.	14	16	- mA
		CML inputs (per input pair) [3][4] V <sub>DDR</sub> = 2.5V or 3.3V, input termination enabled.	33	54	
I <sub>DDRBIAS</sub>	Bias Supply Current	Internal DC-bias circuit when enabled for AC-coupled external clock (per input pair) [3]	13	24	mA
I <sub>DDX</sub>	V <sub>DDX</sub> Supply Current	Crystal oscillator supply	3.5	5	mA
I <sub>DDA</sub>	V <sub>DDA</sub> Supply Current	V <sub>DDA</sub> = any valid supply.	142	151	mA

 $<sup>2. \</sup>quad \text{CLKIN} \\ \text{[1:0]/CLKIN} \\ \text{[1:0]b used as two single-ended clocks rather than as a differential clock.}$ 

Table 38. Power Supply Current [1] (Cont.)

Symbol	Parameter	Conditions	Typical	Maximum	Unit	
I <sub>DDD</sub>	V <sub>DDD</sub> Supply Current	V <sub>DDD</sub> = any valid supply.	69	73	mA	
	V <sub>DDO</sub> Supply Current per	V <sub>DDO</sub> = 1.8V <u>+</u> 5%.	13	20		
	output pair, CMOS mode (both OUT[x] and OUT[x]b	V <sub>DDO</sub> = 2.5V <u>+</u> 5%.	18	24	mA	
	enabled). <sup>[5][6]</sup>	V <sub>DDO</sub> = 3.3V <u>+</u> 5%.	25	33		
IDDO_CMOS	V <sub>DDO</sub> Supply Current per	V <sub>DDO</sub> = 1.8V <u>+</u> 5%.	8	16		
	output pair, CMOS mode (OUT[x] or OUT[x]b enabled,	V <sub>DDO</sub> = 2.5 <u>+</u> 5%.	11	17	mA	
	other output Hi-Z). [5][6]	V <sub>DDO</sub> = 3.3 <u>+</u> 5%.	15	23		
	V <sub>DDO</sub> Supply Current per output pair <sup>[5][6]</sup>	LP-HCSL outputs, 850hm impedance, fast slew rate, 650MHz. V <sub>DDO</sub> = any valid supply.	12	19	mA	
IDDO_LPHCSL		LP-HCSL outputs, 850hm impedance, fast slew rate, 100MHz for PCIe. V <sub>DDO</sub> = any valid supply.	13	17	IIIA	
I <sub>DDO_LVDS</sub>	V <sub>DDO</sub> Supply Current per output pair, LVDS mode [3][4]	V <sub>DDO</sub> = any valid supply.	8	17	mA	
I <sub>DD_IOD</sub>	V <sub>DDO</sub> Divider Supply Current	Portion of VDDO used by IOD	25	28	mA	
I <sub>DD_FOD</sub>	V <sub>DDO</sub> Divider Supply Current	Portion of VDDO used by FOD	38	51	mA	
		Power Down Mode Enabled, VDDs = 1.8V	13	16		
I <sub>DD_PD</sub>	Total Power Down Current	Power Down Mode Enabled, VDDs = 2.5V	15	23	mA	
		Power Down Mode Enabled, VDDs = 3.3V	19	38		

- Current consumption figures represent a worst-case consumption with all functions associated with the particular voltage supply
  enabled and all outputs running at maximum speed, unless otherwise noted. This information is provided to allow for design of
  appropriate power supply circuits that will support all possible register-based configurations for the device. To determine actual
  consumption for the user's device configuration, see Power Considerations. Outputs are not terminated. Values apply to all voltage
  levels unless noted.
- Voltage of the input signal must be appropriate for the V<sub>DDR</sub> voltage supply level when using a DC-coupled connection. For example, when supplying an LVDS input signal that is referenced to a 2.5V supply at its source, the V<sub>DDR</sub> supply must also be 2.5V nominal voltage. When using a 3.3V CMOS input signal, V<sub>DDR</sub> must be 3.3V
- There are two possible input clock pairs. If both are used, the current for each type must be added together. If the external clock(s) is/are
  AC-coupled, the internal DC-bias must be enabled and also added to the total I<sub>DDR</sub> current.
- 4. LVPECL and CML input clocks are not supported when  $V_{DDR}$  = 1.8V.
- 5. I<sub>DDO\_X</sub> denotes the current consumed by each output driver and does not include output divider current. These values are measured at maximum output frequency, unless otherwise stated (200MHz for LVCMOS outputs and 650MHz for differential outputs).
- 6. Please refer to the Output Driver and Output Divider  $V_{DDO}$  Pin Assignments Table to determine the allocation of  $I_{DDO\_IOD}$ ,  $I_{DDO\_FOD}$  and  $I_{DDO\_x}$  to each  $V_{DDO}$  pin.

Table 39. I<sup>2</sup>C/SMBus Bus DC Electrical Characteristics [1]

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Unit
V <sub>IH</sub>	High-level input voltage for SCL_SCLK and SDA_nCS	-	0.7 V <sub>DDD</sub>	-	-	V
V <sub>IL</sub>	Low-level input voltage for SCL_SCLK and SDA_nCS	-	-	-	0.3 V <sub>DDD</sub>	V
V <sub>HYS</sub>	Hysteresis of Schmitt trigger inputs	-	0.05 V <sub>DDD</sub>	-	-	V
V <sub>OL</sub>	Low-level output voltage for SCL_SCLK and SDA_nCS	I <sub>OL</sub> = 4mA	-	-	0.4	V
I <sub>IN</sub>	Input leakage current per pin	-	-10	-	10	μA
C <sub>B</sub>	Capacitive Load for Each Bus Line	-	-	-	400	pF

<sup>1.</sup>  $V_{OH}$  is governed by the  $V_{PUP}$ , the voltage rail to which the pull up resistors are connected.

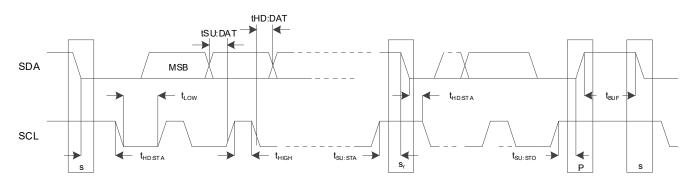


Figure 2. I<sup>2</sup>C/SMBus Slave Timing Diagram

Table 40. I<sup>2</sup>C/SMBus Bus AC Electrical Characteristics

Symbol	Parameter	Conditions	100kHz Class Minimum	100kHz Class Maximum	400kHz Class Minimum	400kHz Class Maximum	Unit
fsмв	SMBus Operating Frequency [1]		10	100	10	400	kHz
tBUF	Bus free time between STOP and START Condition		4.7	-	1.3	-	
thd:sta	Hold time after (REPEATED) START Condition [2]		4	-	0.6	-	μs
tsu:sta	REPEATED START Condition setup time		4.7	-	0.6	-	
tsu:sto	STOP Condition setup time		4	-	0.6	-	
thd:dat	Data hold time [3]		300	-	300	-	nc
tsu:dat	Data setup time		250	-	100	-	ns
tтімеоит	Detect SCL_SCLK low timeout [4]		25	35	25	35	mc
tтімеоит	Detect SDA_nCS low timeout [5]		25	35	25	35	ms
tLOW	Clock low period		4.7	-	1.3	-	110
thigh	Clock high period <sup>[6]</sup>		4	50	0.6	50	μs

Table 40. I <sup>2</sup> C/SMBus Bus AC Electrica	I Characteristics	(Cont.)
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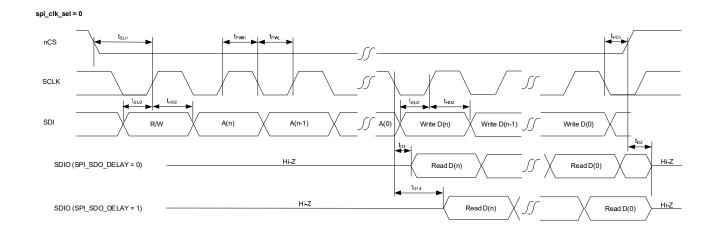
Symbol	Parameter	Conditions	100kHz Class Minimum	100kHz Class Maximum	400kHz Class Minimum	400kHz Class Maximum	Unit
tLOW:SEXT	Cumulative clock low extend time (slave device) [7]		N/A, the RC210xxB do not extend the clock low.			e clock low.	ms
tLOW:MEXT	Cumulative clock low extend time (master device) [8]		N/A, the RC210xxB are not bus masters.				1115
tF	Clock/Data Fall Time [9]		-	120	-	120	
tr	Clock/Data Rise Time [9]		-	120	-	120	ns
tspike	Noise spike suppression time [10]		-	N/A	-	50	

- 1. A master should not drive the clock at a frequency below the minimum f<sub>SMB</sub>. Further, the operating clock frequency should not be reduced below the minimum value of f<sub>SMB</sub> due to periodic clock extending by slave devices as defined in Section 5.3.3 of the SMBus 2.0 Specification. This limit does not apply to the bus idle condition, and this limit is independent from the t<sub>LOW:SEXT</sub> and t<sub>LOW:MEXT</sub> limits. For example, if the SMBCLK is high for t<sub>HIGH:MAX</sub>, the clock must not be periodically stretched longer than 1/f<sub>SMB:MIN</sub> t<sub>HIGH:MAX</sub>. This requirement does not pertain to a device that extends the SMBCLK low for data processing of a received byte, data buffering and so forth for longer than 100µs in a non-periodic way.
- A device must internally provide sufficient hold time for the SMBDAT signal (with respect to the V<sub>IH:MIN</sub> of the SMBCLK signal) to bridge the undefined region of the falling edge of SMBCLK.
- Slave devices may have caused other slave devices to hold SDA low. The maximum time that a device can hold SMBDAT low after the
  master raises SMBCLK after the last bit of a transaction. A slave device may detect how long SDA is held low and release SDA after the
  time out period.
- 4. Devices participating in a transfer can abort the transfer in progress and release the bus when any single clock low interval exceeds the value of t<sub>TIMEOUT:MIN</sub>. After the master in a transaction detects this condition, it must generate a stop condition within or after the current data byte in the transfer process. Devices that have detected this condition must reset their communication and be able to receive a new START condition no later than t<sub>TIMEOUT:MAX</sub>. Typical device examples include the host controller, and embedded controller, and most devices that can master the SMBus. Some simple devices do not contain a clock low drive circuit; this simple kind of device typically may reset its communications port after a start or a stop condition. A timeout condition can only be ensured if the device that is forcing the timeout holds the SMBCLK low for t<sub>TIMEOUT:MAX</sub> or longer.
- 5. The device has the option of detecting a timeout if the SDA nCS pin is also low for this time.
- 6. t<sub>HIGH:MAX</sub> provides a simple guaranteed method for masters to detect bus idle conditions. A master can assume that the bus is free if it detects that the clock and data signals have been high for greater than t<sub>HIGH:MAX</sub>.
- 7. t<sub>HIGH:MAX</sub> provides a simple guaranteed method for masters to detect bus idle conditions. A master can assume that the bus is free if it detects that the clock and data signals have been high for greater than t<sub>HIGH:MAX</sub>.
- 8. t<sub>LOW:SEXT</sub> is the cumulative time a given slave device is allowed to extend the clock cycles in one message from the initial START to the STOP. It is possible that another slave device or the master will also extend the clock causing the combined clock low extend time to be greater than t<sub>LOW:SEXT</sub>. Therefore, this parameter is measured with the slave device as the sole target of a full-speed master.
- 9. The rise and fall time measurement limits are defined as follows:

Rise Time Limits:  $(V_{IL:MAX} - 0.15V)$  to  $(V_{IH:MIN} + 0.15V)$ 

Fall Time Limits:  $(V_{IH:MIN} + 0.15V)$  to  $(V_{IL:MAX} - 0.15V)$ 

10. Devices must provide a means to reject noise spikes of a duration up to the maximum specified value.



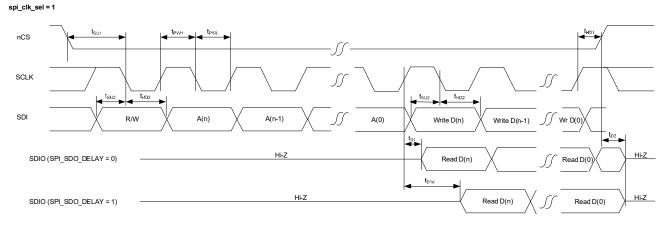


Figure 3. SPI Bus Timing

**Table 41. SPI Slave Interface Electrical Characteristics** 

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Unit
f <sub>OP</sub>	Operating frequency		0.1	-	20	MHz
t <sub>PWH</sub>	SCLK Pulse Width High		-	25	-	
t <sub>PWL</sub>	SCLK Pulse Width Low		-	25	-	ns
t <sub>SU1</sub>	nCS Setup Time to SCLK rising or falling edge		-	7	-	ns
t <sub>HD1</sub>	nCS Hold Time from SCLK rising or falling edge		-	10	-	ns
t <sub>SU2</sub>	SDIO Setup Time to SCLK rising or falling edge		-	4	-	ns
t <sub>HD2</sub>	SDIO Hold Time from SCLK rising or falling edge		-	1	-	ns
t <sub>D1</sub>	Read Data Valid Time from SCLK rising or falling edge with no data delay added		-	6	-	ns
t <sub>D1d</sub>	Read Data Valid Time from SCLK rising or falling edge including half period of SCLK delay added to data timing	[1]	-	6 + half SCLK period	-	ns
t <sub>D2</sub>	SDIO Read Data Hi-Z Time from CS High	[2]	-	10	-	ns

<sup>1.</sup> Adding the extra half period of delay is a register programming option to emulate read data being clocked out on the opposite edge of the SCLK to the write data.

<sup>2.</sup> This is the time until the device releases the signal. Rise time to any specific voltage is dependent on pull-up resistor strength and PCB trace loading.

**Table 42. Power Supply Noise Rejection** 

Symbol	Parameter	Conditions	Minimum	Typical	Maximum	Unit
		f <sub>NOISE</sub> ≤ 1MHz, VDDO[0:6] <sup>[5]</sup>	-146	-112	-	
		f <sub>NOISE</sub> ≤ 1MHz	-76	-69	-	
		f <sub>NOISE</sub> ≤ 100kHz	-138	-135	-	
PSNR	Power Supply Noise Rejection [1][2][3][4]	f <sub>NOISE</sub> ≤ 100kHz	-97	-85	-	dBc
PONK	1.8V operation	100kHz ≤ f <sub>NOISE</sub> ≤ 500kHz	-140	-139	-	abc
	·	100kHz ≤ f <sub>NOISE</sub> ≤ 500kHz	-138	-105	-	
		500kHz ≤ f <sub>NOISE</sub> ≤ 1MHz	-144	-143	-	
		500kHz ≤ f <sub>NOISE</sub> ≤ 1MHz	-93	-90	-	
		f <sub>NOISE</sub> ≤ 1MHz, VDDO[0:6] <sup>[5]</sup>	-146	-112	-	
		f <sub>NOISE</sub> ≤ 1MHz	-76	-69	-	
		f <sub>NOISE</sub> ≤ 100kHz	-138	-135	-	
DOND	Power Supply Noise Rejection [1][3][4][6]	f <sub>NOISE</sub> ≤ 100kHz	-94	-85	-	dD.
PSNR	2.5V or 3.3V operation	100kHz ≤ f <sub>NOISE</sub> ≤ 500kHz	-140	-139	-	dBc
		100kHz ≤ f <sub>NOISE</sub> ≤ 500kHz	-138	-105	-	
		500kHz ≤ f <sub>NOISE</sub> ≤ 1MHz	-144	-143	-	
		500kHz ≤ f <sub>NOISE</sub> ≤ 1MHz	-93	-90	-	

<sup>1.</sup> Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500lfpm. The device will meet specifications after thermal equilibrium has been reached under these conditions.

- 2.  $VDDX = VDDR = VDDR2 = VDDA = VDD[0:6] = 1.8V \pm 5\%$ , VSS = 0V, TA = -40°C to 85°C.
- 3. 50mV peak-to-peak sine wave applied injected on indicated power supply pin(s).
- 4. Noise spur amplitude measured relative to 156.25MHz carrier frequency.
- 5. Excluding VDDOx of the output being measured.
- 6.  $VDDX = VDDR = VDDR2 = VDDA = VDD[0:6] = 2.5V \text{ or } 3.3V \pm 5\%, VSS = 0V, TA = -40^{\circ}C \text{ to } 85^{\circ}C.$

# 3. Functional Description

The RC210xxB is a small-form factor, fully integrated, low-power, high performance frequency synthesizer providing excellent phase jitter on reference clocks for PCI express and Ethernet, while covering a wide range of output frequencies up to 650MHz. It can simultaneously provide low phase jitter non-spreading clocks for Ethernet and storage applications, while providing spread-spectrum PCIe Gen6 clocks.

The following sections provide an overview of the RC210xxB.

# 3.1 Power-Up, Configuration, and Serial Interfaces

The RC210xxB can be powered up and configured in three ways:

- 1. From 1 of 27 internal non-volatile memory using OTP user configurations (UserCfgs)
- 2. From its slave serial interface
- 3. From an external I2C EEPROM

The RC210xxB supports three slave serial interfaces (I2C, SPI, and SMBUS), and one serial master interface (I2C). These interfaces share the same pins, so only one is available at a time.

## 3.2 Input Clocks

The RC210xxB supports one crystal/reference input and up to two differential or four single-ended clock inputs.

## 3.2.1 Crystal/Reference Input

The crystal input supports crystal frequencies of 8MHz to 80MHz. It has programmable internal load capacitors to support crystals with CL = 6pF to 12pF. Internal crystal variants of RC210xxB support a trim value in OTP that can be set during ATE to compensate for initial frequency offset of the internal crystal.

The crystal input may being over-driven with differential or single-ended inputs with proper external terminations. It also supports being over-driven with a clipped sine-wave TCXO with a 0.8V<sub>PP</sub> signal.

The supported frequency range is same as reference clock inputs: 1kHz to 650MHz in differential mode, and 1kHz to 200MHz in single-ended mode.

An available LOS monitor detects the loss of signal on crystal input.

## 3.2.2 Clock Inputs

There are two differential clock inputs that support LVDS, HCSL, or single-ended CMOS logic levels without external terminations. LVPECL or CML clock inputs may be supported with external terminations and/or AC coupling. Internal terminations are available for both HCSL and LVDS logic levels. Additionally, HCSL input terminations support both 100ohm and 85ohm operating environments.

If set to single-ended type, the differential inputs turn into two single-ended inputs. CLKIN0 drives clkin0 internally, CLKIN0b drives clkin1 internally. CLKIN1 drives clkin2 internally, and CLKIN1b drives clkin3 internally. If set to differential type, CLKIN0/CLKIN0b pair drives clkin0 while CLKIN1/CLKIN1b pair drives clkin2. Internal biasing is available for AC-coupled applications. The two clock inputs can be left floating when unused. An available LOS monitor detects the loss of signal on crystal input.

# 3.3 Clock Input Monitor

The APLL input is monitored for Loss of Signal (LOS).

The LOS monitor detects missing edges over a window of several reference clock periods. For the best accuracy, it is recommended to program the window to be equal to at least 8 times that of the measuring clock period.



#### **3.4 APLL**

The APLL is fractional LC-VCO based PLL with an operating range from 9.5GHz to 10.7GHz. Any of the available input clocks can be selected to drive the APLL, and the input clock can be frequency doubled for increased performance. The APLL is temperature compensated for the utmost frequency stability. For synchronous, deterministic requirements, the APLL also supports ZDB mode where CLKIN0 is used for the feedback input.

#### 3.4.1 APLL Lock Detector

The APLL lock detector indicates whether the APLL is locked to a functioning crystal or reference input by monitoring the phase errors. Lock status can be sent on to a GPIO pin or in the register map.

## 3.5 Output Dividers

The RC210xxB provides four integer and three fractional output dividers.

#### 3.5.1 Integer Output Dividers

All four Integer Output Dividers (IOD) are identical. They use a 25-bit divider to provide output frequencies of 1kHz to 650MHz from the VCO clock. Changing IOD values results in an immediate change to the new frequency. Glitch-less squelch and release of the IOD clock is supported. When enabled, this mimics a gapped clock behavior when an IOD frequency is changed.

## 3.5.2 Fractional Output Dividers

There are three Fractional Output Dividers (FOD). Each FOD can divide down the VCO clock to provide frequencies from 1kHz to 650MHz. Each FOD is implemented in two stages. The first stage is an 8-bit fractional divider with Digital Control Delay (DCD) correction. The DCD FOD allows a divide down of the VCO clock to 30MHz to 650MHz. A 17-bit second-stage integer divider with minimum divide ratio of 4 and a maximum ratio of 2\*(2<sup>17</sup>-1) allows output frequencies lower than 30MHz. For output frequencies above 30MHz, this second-stage divider may be bypassed.

#### 3.5.2.1 Spread-Spectrum Clocking

FOD0 and FOD1 support Spread-Spectrum Clocking (SSC).

When SSC is enabled, the spread spectrum engine modulates the FOD divider ratio with a triangular modulation pattern. The modulation can be programmed for either down-spread or center-spread. The SSC modulation frequency can be programmed to a value between 30kHz to 63kHz. The SSC amplitude can be programmed in 0.05% steps to -1.5% for down spread, or ±1.5% for center spread. When turning off SSC, the current modulation cycle completes, returning the output to the non-spreading frequency before the SSC stops.

#### 3.5.2.2 Sync and Phase Adjustment

Each FOD can adjust its output clock phase with a step size of 1/4 VCO period up to about ±20ns. The adjustment can be of either positive or negative directions.

IOD phase adjustment is same as FOD phase adjustment but with a step size of one VCO period.

## 3.6 Clock Outputs

The RC210xxB supports up to 12 differential or 24 single-ended clock outputs or any combination of differential and single-ended clock outputs. Every differential clock output can be programmed as two single-ended clock outputs.

#### 3.6.1 Output Types

The RC210xxB outputs drive HCSL inputs (such as those used in PCIe applications) directly. They use Low-Power HCSL (LP-HCSL) driver technology to eliminate external termination resistors. The LP-HCSL outputs can



be set to 85ohm or 100ohm differential output impedance. The LP-HCSL outputs have selectable output swing and slew rate settings.

The RC210xxB outputs may also be set to LVDS. LVDS outputs require only a 100ohm resistor between the true and complement inputs of the receiver clock input. LVDS outputs have selectable amplitude. Both LVDS and LP-HCSL outputs provide LVPECL and CML-compatible output swing levels by using external AC coupling.

If set to single-ended mode, the output pair can drive either pin or both pins. If both pins are enabled, they can be in phase, or inverted phase. The single-ended outputs support CMOS swings of 1.8V, 2.5V, or 3.3V as determined by their VDDO voltage.

## 3.6.2 Output Banks

0x7

The RC210xxB maps the internal and external frequency sources to output banks, that can be programmed in register out\_bank\_src, according to Table 43. There are up to 12 clock outputs arranged in seven output banks. Each bank sits on its own VDDO (each VDDO also supplies an IOD or FOD according to Table 44).

Bank 0 Bank 1 Bank 2 Bank 3 Bank 4 Bank 5 Bank 6 output\_bank\_src OUT0 OUT1 OUT[2:3] OUT[4:7] OUT[8:9] **OUT10 OUT11** 0x0 IOD0 N/A CLKIN1 0x1 IOD1 N/A XIN REFIN N/A 0x2 N/A IOD2 IOD3 N/A 0x3 N/A 0x4 FOD0 FOD1 0x5 N/A FOD2 0x6

**Table 43. Output Bank Source Mapping** 

Table 44. VDD Pin Assignments for Outputs, Integer Output Dividers, and Fractional Output Dividers

N/A

V <sub>DDO0</sub>	V <sub>DDO1</sub>	V <sub>DDO2</sub>	V <sub>DDO3</sub>	V <sub>DDO4</sub>	V <sub>DDO5</sub>	V <sub>DDO6</sub>	$V_{DDX}$	$V_{DDR}$	$V_{DDD}$	V <sub>DDA</sub>
IOD0, OUT0	IOD1, OUT1	FOD0, OUT[2:3]	FOD1, OUT[4:7]	FOD2, OUT[8:9]	IOD2, OUT10	IOD3, OUT11	XO, XIN_REFIN, XOUT_REFI Nb	GPI[3:0]	SCL_SCLK, SDA_nCS, GPIO[4:0]	PLL

CLKIN0

# 4. Application Information

# 4.1 Recommendations for Unused Input and Output Pins

#### 4.1.1 CLKIN/CLKINb [1:0] Inputs

For applications that do not require the use of reference clock inputs, both CLKIN and CLKINb should be left floating. If the CLKIN/CLKINb inputs are connected but not used by the device, Renesas recommends that CLKIN and CLKINb be connected to static signals, not active signals.

#### 4.1.2 LVCMOS Control Pins

LVCMOS control pins have selectable internal pull-ups and/or pull-downs. Additional resistance is not required but may be added for additional protection. A  $10k\Omega$  resistor can be used.

# 4.1.3 LVCMOS Outputs

Any LVCMOS output may be left floating if unused. There should be no trace attached. The mode of the output buffer should be set to high impedance state to avoid unnecessary noise generation.

#### 4.1.4 Differential Outputs

All unused differential outputs may be left floating. There should be no trace attached. Both sides of the differential output pair should be treated the same, either left floating or terminated.

# 4.2 CLKIN/CLKINb Clock Inputs Interface

The RC210xxB provides a programmable input buffer for reference clock inputs, as shown in Figure 4. This programmable buffer supports most standard signaling protocols with no need for external termination components at the receiver end of the transmission line.

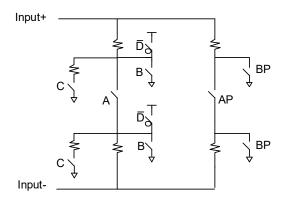


Figure 4. Programmable Input Buffer Logical Diagram

By making appropriate register selections, the switches labeled in Figure 4 can be closed as shown in Table 45 to support the indicated protocols. With the switches closed as indicated, the input buffer will operate as shown in Figure 5 for the various input reference signal protocols. Note that HCSL is used in both 100ohm and 85ohm transmission line environments and this input buffer supports both with no external terminations required.

Input Signaling Protocol	Switches Closed	V <sub>DDR</sub> Voltage Required
2.5V LVPECL	A, C	2.5V
3.3V LVPECL	A, C	3.3V
LVDS (85 ohms)	A, AP	1.8V / 2.5V / 3.3V
LVDS (100 ohms)	A	1.8V / 2.5V / 3.3V
1.8V LVCMOS	-	1.8V
2.5V LVCMOS	-	2.5V
3.3V LVCMOS	-	3.3V
CML	D	3.3V
HCSL (42.5 ohms)	B, BP	1.8V / 2.5V / 3.3V
HCSL (42 ohms)	В	1.8V / 2.5V / 3.3V
Externally AC-coupled <sup>[1]</sup>	-	1.8V / 2.5V / 3.3V

Table 45. Input Buffer Programming Options for Specific Signaling Protocols

In this mode of operation, AC-coupling capacitors must be used to isolate the voltage level of the transmitter from the receiver. The signal
must be properly terminated on the transmitter side of the AC-coupling capacitors. Bias terminations are needed between the ACcoupling capacitors and the RC210xxB.

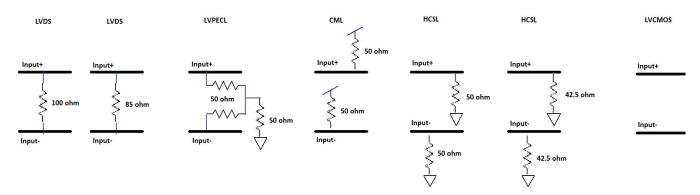


Figure 5. Input Buffer Behavior by Protocol

# 4.3 Overdriving the XTAL Interface

## 4.3.1 XTAL Interface Set to Input Buffer Mode

The RC210xxB has two bits to disconnect the internal XO and enable input buffer mode on the XIN\_REFIN/XOUT\_REFINb pins. First, setting sel\_ib\_xo = 0, disconnects the internal XO. Next, setting xo\_ib\_cmos\_sel = 1 enables the LVCMOS input clock path. Setting these two bits as indicated removes any AC-coupling or input voltage requirements for overdriving the XTAL interface. Note that the maximum input swing is still governed by the VDDX supply rail. Once set to Input Buffer Mode, the input can be directly driven with a single-ended or differential oscillator. There is no internal termination capability when using the XTAL interface in input buffer mode. Other than this lack of internal terminations, the input buffer mode has all capabilities of the CLKIN/CLKINb interfaces.

#### 4.3.2 XTAL Interface in XO Mode, Input Buffer Mode Not Selected

If the two bits mentioned above are not set as indicated, then there is a limitation of 1.2V on the XIN REFIN/XOUT REFINb pins. Input buffer mode is preferred as described in section 4.3.1.

The XIN\_REFIN input can be overdriven by an LVCMOS driver or by one side of a differential driver through an AC coupling capacitor. The XOUT pin can be left floating. The amplitude of the input signal should be between



500mV and 1.2V, and the slew rate must be ≥0.2V/ns. For 1.2V LVCMOS, inputs can be DC-coupled into the device as shown in Figure 6. For LVCMOS drivers with > 1.2V swing, the amplitude must be reduced from full swing to at least 1.2V in order to prevent signal interference with the power rail. The sum of the driver output impedance and Rs must equal the transmission line impedance to prevent overshoot and undershoot.

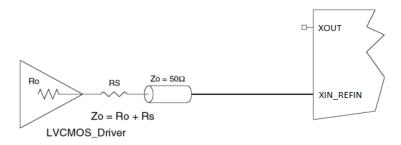


Figure 6. 1.2V LVCMOS Driver to XTAL Input Interface

Figure 7 shows an example of the interface diagram for a high-speed 3.3V LVCMOS driver. This configuration requires that the sum of the output impedance of the driver (Ro) and the series resistance (Rs) equal the transmission line impedance. This can be done in one of two ways. First, R1 and R2 in parallel should equal the transmission line impedance. We also need to scale the 3.3V LVCMOS swing to 1.2V (~1/3 of the swing). This yields R1 = 2 x R2 while R1 || R2 =  $50\Omega$ . Solving for a  $50\Omega$  ohm system gives R1 =  $150\Omega$  and R2 =  $75\Omega$ . The values of the resistors can be increased to reduce the loading for a slower and weaker LVCMOS driver. Different scaling factors are required for 2.5V and 1.8V LVCMOS drivers.

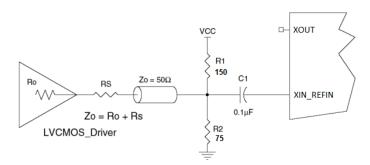


Figure 7. LVCMOS Driver to XTAL Input Interface

Figure 8 shows an example of the interface diagram for an LVPECL driver. This is a standard LVPECL termination with one side of the driver feeding the XIN\_REFIN input. Renesas recommends that all components in the schematics be placed in the layout. Though some components may not be used by the application, they can be used for debugging purposes.

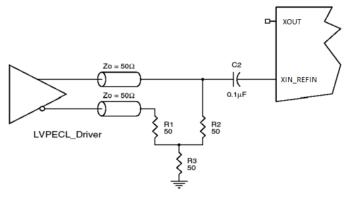


Figure 8. LVPECL Driver to XTAL Input Interface

## 4.4 Differential Output Terminations

## 4.4.1 Direct-Coupled LP-HCSL Termination

For the LP-HCSL differential protocol, the following termination scheme is recommended (see Figure 9). The RC210xxB supports internal source terminations (see Figure 9) for 85 ohm or 100 ohm differential transmission lines. No external components are needed.

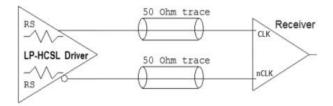


Figure 9. Standard HCSL Termination

## 4.4.2 Direct-Coupled LVDS Termination

For LVDS differential protocol, the following termination scheme is recommended (see Figure 10). The recommended value for the termination impedance ( $Z_T$ ) is between  $90\Omega$  and  $132\Omega$ . The actual value should be selected to match the differential impedance ( $Z_0$ ) of the transmission line. A typical point-to-point LVDS design uses a  $100\Omega$  parallel resistor at the receiver in a  $100\Omega$  differential transmission-line environment. In order to avoid any transmission-line reflection issues, any external components should be surface-mounted and must be placed as close to the receiver as possible.

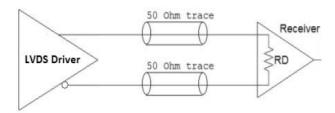


Figure 10. Standard LVDS Termination

#### 4.4.3 AC-Coupled Differential Terminations for Other Protocols

Alternate differential protocols including LVPECL, CML and SSTL can be supported with AC-coupled LP-HCSL outputs. Figure 11 shows a typical AC-coupled termination scheme for a  $100\Omega$  differential transmission-line environment. The RC210xxB supports a differential swing of 1.6V or 1.8V in LP-HCSL mode.

No terminations are needed between the RC210xxB and the AC-coupling capacitors. The resistors on the receiver side of the AC-coupling capacitors provide an appropriate voltage bias for the particular receiver. Finally, a  $100\Omega$  resistor across the differential pair (located near the receiver) attenuates reflections that may corrupt the clock signal integrity.

Often, receivers used with a high-performance device like the RC210xxB are equipped with internal terminations, voltage biasing, and even AC-coupling. Please consult your particular the receiver specification to determine if any or all of the indicated external components in Figure 11 are needed.

Refer to *Driving LVPECL*, *LVDS*, *CML*, and *SSTL Logic with Renesas' "Universal" Low-Power HCSL Outputs"* (AN-891) on the RC210xxB product page for additional information on both re-biasing and amplitude attenuation.

If a smaller differential swing is desired as a starting point, refer to "LVDS Termination" in *Quick Guide - Output Terminations (AN-953)* located on the RC210xxB product page.

Please contact Renesas for additional support, if necessary.

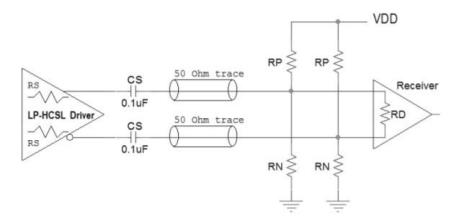


Figure 11. AC-Coupling Termination

# 4.5 Crystal Recommendations

For the latest vendor / frequency recommendations, please contact Renesas.

## 4.6 External I<sup>2</sup>C Serial EEPROM Recommendations

An external I<sup>2</sup>C EEPROM can be used to store configuration data, please contact Renesas for specific recommendations. A specific configuration code is required for the devices to access an external I<sup>2</sup>C serial EEPROM at power up. See the ordering information.

#### 4.7 Power Considerations

The electrical characteristics tables provide current consumption values for various blocks and output configurations, and can be used to estimate total current consumption for a particular design. The Renesas IC Toolbox, available on the Renesas website, can also be used to estimate current consumption. A quick note on terms used in this section: "power rail" refers to the power connection to a particular VDD pin. This means that different VDD pins might be connected to the same voltage, yet may also be connected to different power rails. We will use "power rail" when discussing power sequencing considerations.

## 4.7.1 Power Sequencing Considerations

The RC210xxB has no specific power sequencing requirements. The design software may be used to disconnect unused power supply pins in the silicon, which then allows the user to leave these unused supply pins unconnected. These unused pins are then removed from power sequencing considerations.

The RC210xxB also has two GPIO functions (PWRGD/PWRDN# or PWRGD/RESTART#) which give the user more control over power up timing in applications environments such as data centers. These environments often need to hold clocks in reset until the devices receiving the clocks have completed their power-up housekeeping and are ready to receive clocks. We discuss operation without this GPIO function first, followed by a discussion with this GPIO function.

#### 4.7.1.1 Power-Up Operation without PWRGD/PWRDN# or PWRGD/RESTART# Function

When PWRGD/PWRDN# or PWRGD/RESTART# is not used, the RC210xxB outputs are gated by the last VDD pin to become valid. See Table 18 for details.



#### 4.7.1.2 Power-Up Using PWRGD/PWRDN# or PWRGD/RESTART#

Using the PWRGD/PWRDN# or PWRGD/RESTART# GPIO configuration gives the user more control over power-up behavior. Holding the pin low, pauses the RC210xxB start-up sequence until the pin is asserted high. This pin should be held low from the very beginning of the power up sequence. The pin function is defined as follows:

- PWRGD means Power is Good (active high). Asserting PWRGD/PWRDN# or PWRGD/RESTART# high after all power rails are valid, tells the RC210xxB that power is good, power up completely and begin operation. The first high assertion of PWRGD/PWRDN# loads a new configuration into the device (selected by external pins if there are multiple configurations). Subsequent high assertions of PWRGD/PWRDN# return to the previously loaded configuration.
- PWRDN# means enter Power Down (active low). Asserting PWRGD/PWRDN# low puts (or keeps) the RC210xxB in a low power state, turning off as much internal logic as possible (including the APLL) to save the most power while keeping the power rails active. Returning from PWRDN# by asserting PWRGD/PWRDN# high resumes the previous operating state.
- RESTART# means Restart (active low). Asserting PWRGD/RESTART# low resets the RC210xxB and prepares
  it for a complete restart of entire power up sequence without having to remove the power supplies. Returning
  from RESTART# by asserting the PWRGD/RESTART# pin high loads a new configuration, which may or may
  not be different from the one used before RESTART# asserted low.

Figure 12 shows use of a PWRGD/PWRDN# or PWRGD/RESTART# input to hold the entire RC210xxB until all power supply rails reach 1.62V. The PWRGD\PWRDN# pin must be held low for at least t<sub>HOLD</sub>after the last VDDO pin reaches 1.62V. It may be held longer. Using the PWRGD/PWRDN# or PWRGD/RESTART# GPIO function isolates the RC210xxB from changes to power supply sequencing that may be induced by changes to other devices in the system. A configuration can contain PWRGD/PWRDN# or PWRGD/RESTART#, not both. If the power down state is not used, PWRGD/RESTART# is the preferred configuration, since it allows more flexibility with GPI/GPIO assignment.

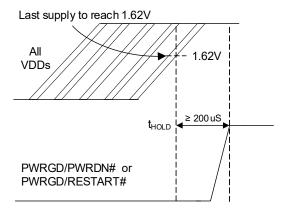


Figure 12. Power Supply Sequencing Recommendations - Power-Up Using PWRGD/PWRDN# or POR#

## 5. Thermal Information

#### 5.1 VFQFPN ePad Thermal Release Path

In order to maximize both the removal of heat from the package and the electrical performance, a land pattern must be incorporated on the Printed Circuit Board (PCB) within the footprint of the package corresponding to the exposed metal pad or exposed heat slug on the package, as shown in Figure 13. The solderable area on the PCB, as defined by the solder mask, should be at least the same size/shape as the exposed pad/slug area on the package to maximize the thermal/electrical performance. Sufficient clearance should be designed on the PCB between the outer edges of the land pattern and the inner edges of pad pattern for the leads to avoid any shorts.

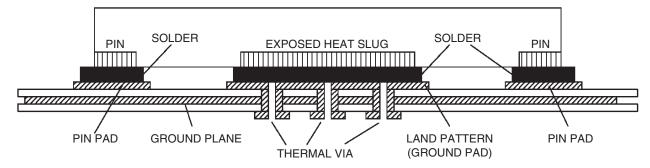


Figure 13. P.C. Assembly for Exposed Pad Thermal Release Path - Side View

While the land pattern on the PCB provides a means of heat transfer and electrical grounding from the package to the board through a solder joint, thermal vias are necessary to effectively conduct from the surface of the PCB to the ground plane(s). The land pattern must be connected to ground through these vias. The vias act as "heat pipes." The number of vias (i.e., "heat pipes") are application specific and dependent on the package power dissipation as well as electrical conductivity requirements. Thus, thermal and electrical analysis and/or testing are recommended to determine the minimum number needed.

Maximum thermal and electrical performance is achieved when an array of vias is incorporated in the land pattern. It is recommended to use as many vias connected to ground as possible. It is also recommended that the via diameter should be 12 to 13mils (0.30 to 0.33 mm) with 1oz copper via barrel plating. This is desirable to avoid any solder wicking inside the via during the soldering process which may result in voids in solder between the exposed pad/slug and the thermal land. Precautions should be taken to eliminate any solder voids between the exposed heat slug and the land pattern. Note: These recommendations are to be used as a guideline only. For further information, please refer to the Application Note on the Surface Mount Assembly of Amkor's Thermally/ Electrically Enhance Lead frame Base Package, Amkor Technology.

#### 5.2 Thermal Characteristics

Table 46. Thermal Characteristics (48-pin with External Crystal) [1]

Symbol	Parameter	Value	Unit
θ <sub>JC</sub>	Theta J <sub>C</sub> . Junction to Device Case Thermal Coefficient <sup>[2]</sup>	20.1	
$\theta_{JB}$	Theta J <sub>B</sub> . Junction to Board Thermal Coefficient <sup>[2]</sup>	1.9	
	Junction to Ambient Air Thermal Coefficient (still air)	25.8	°C/W
Δ.	Junction to Ambient Air Thermal Coefficient 1 m/s air flow	21.5	C/VV
$\theta_{JA}$	Junction to Ambient Air Thermal Coefficient 2 m/s air flow	18.8	
	Junction to Ambient Air Thermal Coefficient 3 m/s air flow	17.9	
-	Moisture Sensitivity Rating (Per J-STD-020)	3	N/A

<sup>1.</sup> JEDEC Standard PCB (101.6 x 114.5 x 1.6 mm) with two ground and two voltage planes.

<sup>2.</sup> Assumes ePad is connected to a ground plane using a grid of 25 thermal vias.

Table 47. Thermal Characteristics (40-pin with External Crystal) [1]

Symbol	Parameter	Value	Unit
$\theta_{JC}$	Theta J <sub>C</sub> . Junction to Device Case Thermal Coefficient <sup>[2]</sup>	35.7	
$\theta_{JB}$	Theta J <sub>B</sub> . Junction to Board Thermal Coefficient <sup>[2]</sup>	1.9	
	Junction to Ambient Air Thermal Coefficient (still air)	28.9	°C/W
۵	Junction to Ambient Air Thermal Coefficient 1 m/s air flow	25.6	C/VV
$\theta_{JA}$	Junction to Ambient Air Thermal Coefficient 2 m/s air flow	23	
	Junction to Ambient Air Thermal Coefficient 3 m/s air flow	21.8	
-	Moisture Sensitivity Rating (Per J-STD-020)	3	N/A

<sup>1.</sup> JEDEC Standard PCB (101.6  $\times$  114.5  $\times$  1.6 mm) with two ground and two voltage planes.

Table 48. Thermal Characteristics (48-pin with Internal Crystal) [1]

Symbol	Parameter	Value	Unit
$\theta_{JC}$	Theta J <sub>C</sub> . Junction to Device Case Thermal Coefficient <sup>[2]</sup>	24.5	
$\theta_{JB}$	Theta J <sub>B</sub> . Junction to Board Thermal Coefficient <sup>[2]</sup>	15	
	Junction to Ambient Air Thermal Coefficient (still air)	37.3	°C/W
Δ	Junction to Ambient Air Thermal Coefficient 1 m/s air flow	35	C/VV
$\theta_{JA}$	Junction to Ambient Air Thermal Coefficient 2 m/s air flow	33	
	Junction to Ambient Air Thermal Coefficient 3 m/s air flow	32	
-	Moisture Sensitivity Rating (Per J-STD-020)	3	N/A

<sup>1.</sup> JEDEC Standard PCB (101.6 x 114.5 x 1.6 mm) with two ground and two voltage planes.

Table 49. Thermal Characteristics (40-pin with Internal Crystal) [1]

Symbol	Parameter	Value	Unit
$\theta_{JC}$	Theta J <sub>C</sub> . Junction to Device Case Thermal Coefficient <sup>[2]</sup>	35	
$\theta_{JB}$	Theta J <sub>B</sub> . Junction to Board Thermal Coefficient <sup>[2]</sup>	52.4	
	Junction to Ambient Air Thermal Coefficient (still air)	70.7	°C/W
۵	Junction to Ambient Air Thermal Coefficient 1 m/s air flow	65.9	C/VV
$\theta_{JA}$	Junction to Ambient Air Thermal Coefficient 2 m/s air flow	62.5	
	Junction to Ambient Air Thermal Coefficient 3 m/s air flow	61	
-	Moisture Sensitivity Rating (Per J-STD-020)	3	N/A

<sup>1.</sup> JEDEC Standard PCB (101.6 × 114.5 × 1.6 mm) with two ground and two voltage planes.

<sup>2.</sup> Assumes ePad is connected to a ground plane using a grid of 16 thermal vias.

<sup>2.</sup> Assumes ePad is connected to a ground plane using a grid of 25 thermal vias.

<sup>2.</sup> Assumes ePad is connected to a ground plane using a grid of 16 thermal vias.

Table 50. Thermal Characteristics (32-pin with Internal Crystal) [1]

Symbol	Parameter	Value	Unit
$\theta_{JC}$	Theta J <sub>C</sub> . Junction to Device Case Thermal Coefficient <sup>[2]</sup>	61.2	
$\theta_{JB}$	Theta J <sub>B</sub> . Junction to Board Thermal Coefficient <sup>[2]</sup>	7.4	
	Junction to Ambient Air Thermal Coefficient (still air)	40.3	°C/W
0	Junction to Ambient Air Thermal Coefficient 1 m/s air flow	37.4	C/VV
$\theta_{JA}$	Junction to Ambient Air Thermal Coefficient 2 m/s air flow	34.8	
	Junction to Ambient Air Thermal Coefficient 3 m/s air flow	33	
-	Moisture Sensitivity Rating (Per J-STD-020)	3	N/A

<sup>1.</sup> JEDEC Standard PCB (101.6  $\times$  114.5  $\times$  1.6 mm) with two ground and two voltage planes.

<sup>2.</sup> Assumes ePad is connected to a ground plane using a grid of 4 thermal vias.

# 6. Package Outline Drawings

The package outline drawings are located at the end of this document and are accessible from the Renesas website. The package information is the most current data available and is subject to change without revision of this document.

# 7. Marking Diagrams

RC21008
BdddGND
#YYWW\$

RC21008Bddd

- Lines 1 and 2: part number.
  - "ddd" indicates preprogrammed device custom configuration dash code.
- Line 3:
  - "#" indicates the stepping number.
  - "YYWW" indicates the last two digits of the year and work week the part was assembled.
  - "\$" indicates the mark code.

RC21012B dddGNA #YYWW\$

RC21012Bddd

- Lines 1 and 2: part number.
  - "ddd" indicates preprogrammed device custom configuration dash code.
- Line 3:
  - "#" indicates the stepping number.
  - "YYWW" indicates the last two digits of the year and work week the part was assembled.
  - "\$" indicates the mark code.

78.1 S DC

RC21005BQdd

Due to package construction, the marking of the RC21005BQdd is that of the integrated crystal. The "dd" dash-code is encoded in a unique digital register "marking" that is documented in the addendum. The crystal marking is defined as follows:

- Line 1: Abbreviated notation of the 78.125MHz crystal frequency.
- Line 2: "S" is crystal vendor. "DC" is the date code which is encoded as follows:

Last Digit of Year	D (Year Code)	Month	C (Month Code)
1	Α	1	Α
2	В	2	В
3	С	3	С
4	D	4	D
5	E	5	Е
6	F	6	F
7	G	7	G
8	Н	8	Н
9	J	9	J
0	K	10	K
-	-	11	L
-	-	12	M

RC21008 BQddGL2 #YWW\*\*\$

- Lines 1 and 2: part number.
  - "dd" indicates preprogrammed device custom configuration dash code.
- Line 3:
  - "#" indicates the stepping number.
  - "YWW" indicates the last digit of the year and work week the part was assembled.
  - "\*\*" indicates the lot sequential number

#### RC21008BQdd



- Lines 1 and 2: part number.
  - "dd" indicates preprogrammed device custom configuration dash code.
- Line 3:
  - "#" indicates the stepping number.
  - "YYWW" indicates the last two digits of the year and work week the part was assembled.
  - "\*\*\*" indicates the lot sequential number.

#### RC21012BQdd

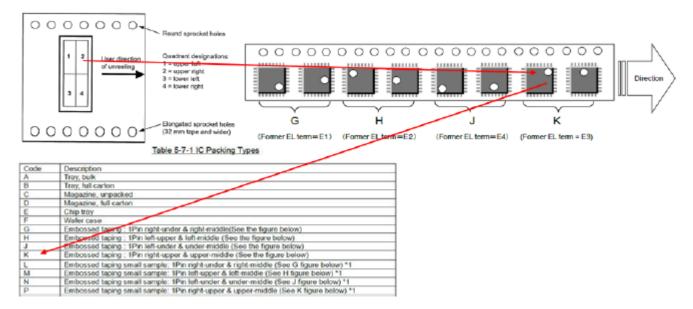


Figure 14. Pin 1 Orientation in Tape and Reel Packaging

# 8. Ordering Information

Table 51. Ordering Information

Part Number	Description	Number of Output Pairs	Carrier Type [1]	Pkg. Desc.	Temp. Range
RC21008B000GND#BB0		8	Tray	5 × 5 × 0.9 mm, 40-VFQFPN	
RC21008B000GND#KB0	Un-programmed part with external crystal. I2C	0	Tape and Reel		-40° to
RC21012B000GNA#BB0	address is 0x09.	12	Tray	6 × 6 × 0.9 mm,	+85°C
RC21012B000GNA#KB0		12	Tape and Reel	48-VFQFPN	
RC21008B001GND#BB0	Un-programmed part with	8	Tray	5 × 5 × 0.9 mm,	
RC21008B001GND#KB0	external crystal for use with external I2C	0	Tape and Reel	40-VFQFPN	-40° to
RC21012B001GNA#BB0	EEPROM.		Tray	6 × 6 × 0.9 mm,	+85°C
RC21012B001GNA#KB0	I2C address is 0x09 after I2C EEPROM is loaded.	12	Tape and Reel	48-VFQFPN	
RC21008BdddGND#BB0 [2]	Preprogrammed part with external crystal.	0	Tray	5 × 5 × 0.9 mm,	
RC21008BdddGND#KB0 [2]		8	Tape and Reel	40-VFQFPN	-40° to
RC21012BdddGNA#BB0 [2]		12	Tray	6 × 6 × 0.9 mm,	+85°C
RC21012BdddGNA#KB0 [2]		12	Tape and Reel	48-VFQFPN	
RC21005BQ00GL2#BB0	Un-programmed part with	E	Tray	4 × 4 × 1.2 mm,	
RC21005BQ00GL2#KB0		5	Tape and Reel	32-LGA	
RC21008BQ00GL2#BD0		8	Tray	5 × 5 × 1.7 mm,	-40° to
RC21008BQ00GL2#KD0	internal crystal. I2C address is 0x09.	0	Tape and Reel	40-LGA	+85°C
RC21012BQ00GL3#BB0		12	Tray	6 × 6 × 0.9 mm,	
RC21012BQ00GL3#KB0		12	Tape and Reel	48-LGA	
RC21005BQ01GL2#BB0		5	Tray	4 × 4 × 1.2 mm,	
RC21005BQ01GL2#KB0	Un-programmed part with internal crystal for use	3	Tape and Reel	32-LGA	
RC21008BQ01GL2#BD0	with external I2C	8	Tray	5 × 5 × 1.7 mm,	-40° to
RC21008BQ01GL2#KD0	EEPROM. 12C address is 0x09 after	0	Tape and Reel	40-LGA	+85°C
RC21012BQ01GL3#BB0	I2C EEPROM is loaded.	12	Tray	6 × 6 × 0.9 mm,	
RC21012BQ01GL3#KB0		12	Tape and Reel	48-LGA	
RC21005BQddGL2#BB0 [2]		5	Tray	4 × 4 × 1.2 mm,	
RC21005BQddGL2#KB0 [2]		o o	Tape and Reel	32-LGA	
RC21008BQddGL2#BD0 [2]	Preprogrammed part with	8	Tray	5 × 5 × 1.7 mm,	-40° to
RC21008BQddGL2#KD0 [2]	internal crystal.	O	Tape and Reel	40-LGA	+85°C
RC21012BQddGL3#BB0 [2]		12	Tray	6 × 6 × 0.9 mm,	
RC21012BQddGL3#KB0 [2]		12	Tape and Reel	48-LGA	

<sup>1.</sup> Tape and Reel pin 1 orientation follows EIA-481-D unless noted.

<sup>2.</sup> Replace "ddd" or "dd" with the preprogrammed configuration code provided by Renesas in response to a custom configuration request.

# 9. Revision History

Apr 5, 2024      Apr 5, 2024      Apr 5, 2024      Added cross-references in Table 1, Table 2, Table 3, Table 4, and Table 5 to Tall      Mar 13, 2024      Apr 5, 2024      Added cross-references in Table 1, Table 2, Table 3, Table 4, and Table 5 to Tall      Updated several part numbers in Ordering Information (RC21012BQ00GL3#BBRC21012BQ00GL3#BB0, and RC21012BQ01GL3#BB0, and RC21012BQ01GL3#BB0)      Apr 5, 2024      Apr 6, 2024      Apr 6, 2024      Apr 7, 2024      Apr 7	ole 8.
RC21012BQ00GL3#KB0, RC21012BQ01GL3#BB0, and RC21012BQ01GL3#k	
<ul> <li>Updated block diagram on front page to show the RC21005 variant.</li> <li>Added BQ part information to Front page, Pin Information, Table 48, Table 49, 1</li> <li>Marking Diagrams, and Ordering Information</li> <li>Rearranged Ordering Information for readability.</li> <li>Completed other minor changes.</li> </ul>	Table 50,
<ul> <li>Jan 9, 2024</li> <li>Updated the typical and maximum values for t<sub>ΦAPLL</sub> in Table 22.</li> <li>Updated the document to the latest template.</li> </ul>	
Dec 21, 2023	
1.12 Nov 10, 2023 • Corrected a package link in Ordering Information.	
1.11 Oct 27, 2023 • Updated the down-spread maximum value in Table 33	
1.10 Aug 15, 2023 • Corrected the description of the RC21008B000GND#BB0 part in Ordering Infor	mation.
1.09 May 31, 2023 • Changed t <sub>HOLD</sub> to 200uS from 200mS in Figure 12.	
1.08 May 8, 2023 • Updated the device block diagram in Figure 1	
1.07 Apr 14, 2023 • Corrected an RC21005BQ part number in Ordering Information	
<ul> <li>Updated document for B revision as follows:         <ul> <li>Updated front page references to B revision and simplified the block diagram</li> <li>Added RC21012BQ pin assignments and pin descriptions.</li> <li>Added RC21005BQ pin assignments and pin descriptions.</li> <li>Updated ordering information with new devices and revisions.</li> <li>Changed ePad outline and ePad text in the Pin Diagrams to grey color to hig view is Top View and the ePad is on the bottom of the package.</li> <li>Added thermal data for 005BQ and 012BQ package.</li> <li>Corrected all theta ja descriptions from 0, 1, 3, and 5 m/s airflow to 0, 1, 2, an</li> <li>Updated Power Considerations for the B-rev silicon.</li> </ul> </li> </ul>	hlight that the
<ul> <li>1.05</li> <li>Nov 22, 2022</li> <li>Added LVCMOS AC/DC characteristics tables (see Table 23 to Table 25).</li> <li>Completed an extensive update to Power Considerations, specifically power se considerations.</li> <li>Clarified Overdriving the XTAL Interface.</li> </ul>	quencing
<ul> <li>Changed the minimum value for t<sub>PU</sub> in Table 8.</li> <li>Removed references to RC21005A pending final qualification. For the latest doc this device, please contact Renesas.</li> <li>Completed other minor changes.</li> </ul>	umentation on
Updated the Marking Diagrams and Ordering Information, added 01 and 001 do indicate configurations that load from external I2C EEPROMs. Updated footnot     Updated Power Sequencing Considerations.	
1.02 Aug 31, 2022 - Completed minor updates to various Electrical Characteristics values.	

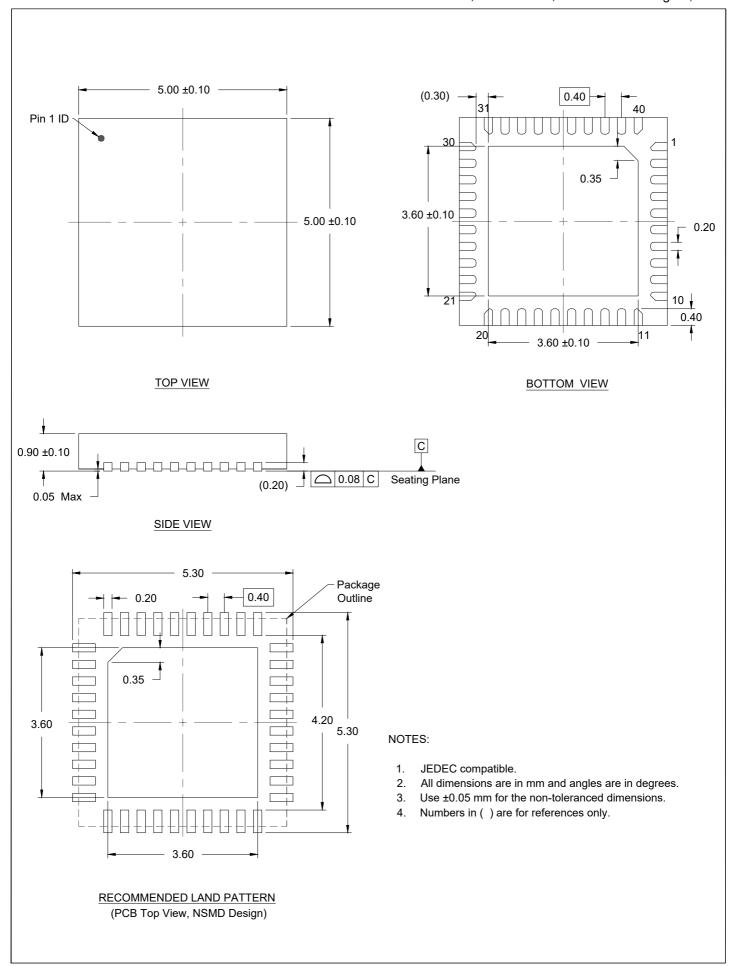
## RC210xxB Datasheet

Revision	Date	Description
1.01	Aug 9, 2022	<ul> <li>Corrected a typo in Pin Assignments – RCxx012A.</li> <li>Completed minor updates to various Electrical Characteristics values.</li> <li>Completed other minor changes.</li> </ul>
1.00	Jul 22, 2022	Initial release.





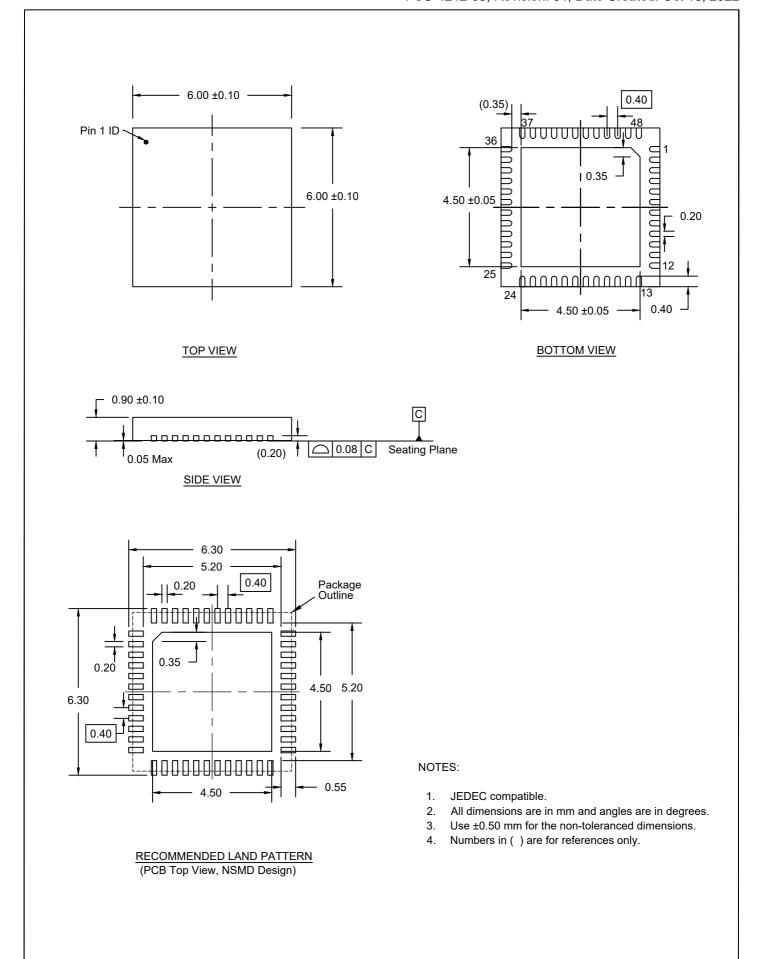
Package Code:NDG40P3 40-VFQFPN 5.0 x 5.0 x 0.9 mm Body, 0.4 mm Pitch PSC-4292-03, Revision: 02, Date Created: Aug 30, 2022







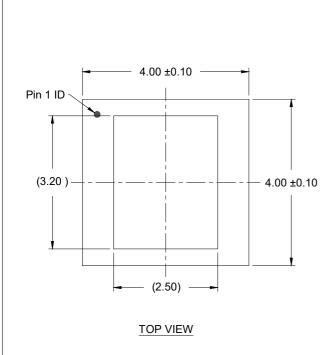
Package Code: NDG48P4 48-VFQFPN 6.0 x 6.0 x 0.9 mm Body, 0.4 mm Pitch PSC-4212-05, Revision: 01, Date Created: Oct 18, 2022

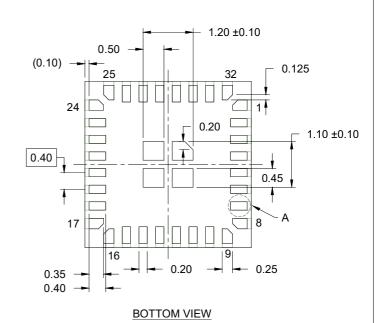


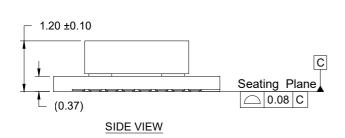


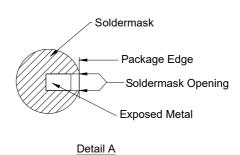


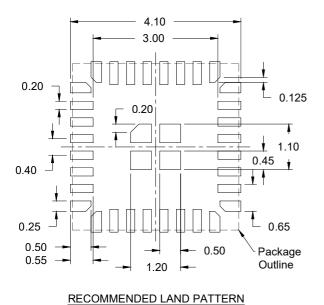
Package Code: LTX32D1 32-LGA 4.0 x 4.0 x 1.20 mm Body, 0.40 mm Pitch PSC-4913-01, Revision: 02, Date Created: Oct 11, 2022











(PCB Top View, NSMD Design)

#### NOTES:

- 1. JEDEC compatible.
- 2. All dimensions are in mm and angles are in degrees.
- 3. Use ±0.50 mm for the non-toleranced dimensions.
- 4. Numbers in ( ) are for references only.





Package Code: LTG40D1 40-LGA 5.0 x 5.0 x 1.70 mm Body, 0.40 mm Pitch PSC-4864-01, Revision: 03, Date Created: May 26, 2023

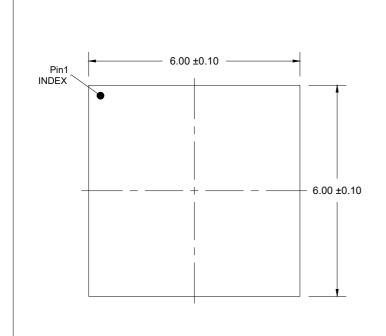
3.03 ±0.10 5.00 ±0.10 (0.10) -1.17 Pin 1 ID 39 31 30 🖂 0.69 → 3.03 ±0.10 5.00 ±0.10 1.17 21 10 0.30 -0.40 TOP VIEW **BOTTOM VIEW** Soldermask Package Edge 1.70 ±0.10 С Soldermask Opening Seating Plane **Exposed Metal** SIDE VIEW Detail A 5.10 0.69 NOTES: 3.03 JEDEC compatible. 0.40 1.17 All dimensions are in mm and angles are in degrees. Use ±0.05 mm for the non-toleranced dimensions. Numbers in ( ) are for references only. 0.20 Package 0.45 Outline 3.03 RECOMMENDED LAND PATTERN (PCB Top View, NSMD Design)





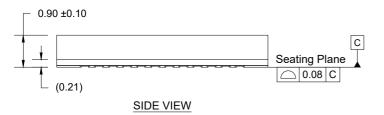
Package Code: LGV48D1 48-LGA 6.0 x 6.0 x 0.90 mm Body, 0.4mm Pitch

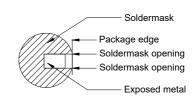
PSC-4943-01, Revision: 02, Date Created: May 26, 2023



- (0.075) 1.40 37 36 0.35 1.55 (<u>1</u>12 25 13 - 0.20 0.325

**TOP VIEW** 





Detail A

**BOTTOM VIEW** 

Package 5.20 Outline 1.55 0.20 1.15

(PCB Top View) (Lead pad - NSMD Design; Thermal pad - SMD Design)

NOTES:

- JEDEC compatible.
- All dimensions are in mm and angles are in degrees.
- Use ±0.05 mm for the non-toleranced dimensions.
- Numbers in ( ) are for reference only.

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